







**AWRL1432** SWRS296B - JULY 2023 - REVISED JUNE 2024

## AWRL1432 Single-Chip 76- to 81-GHz Automotive Radar Sensor

#### 1 Features

- **FMCW Transceiver** 
  - Integrated PLL, transmitter, receiver, baseband
  - 76-81GHz coverage with 5GHz continuous bandwidth
  - 3 receive channels and 2 transmit channels
  - Short range
  - 11dBm typical output power per Tx
  - 14dB typical noise figure
  - -89dBc/Hz typical phase noise at 1MHz
  - FMCW operation
  - 5MHz IF bandwidth, real-only Rx channels
  - Ultra-accurate chirp engine based on fractional-N PLL
  - Per transmitter binary phase shifter
- Processing elements
  - Arm® M4F® core with single precision FPU (160 MHz)
  - TI Radar Hardware Accelerator (HWA 1.2) for FFT, Log Magnitude, and CFAR operations (80MHz)
- Supports multiple low-power modes
  - Idle mode and deep sleep mode
- Power management
  - 1.8V and 3.3V IO support
  - Built-in LDO network for enhanced PSRR
  - BOM-Optimized and Power-Optimized modes
  - One or two power rails for 1.8V IO mode, two or three power rails for 3.3V IO mode
- Package size of FCCSP device: 6.45mm x 6.45mm
- Built-in calibration and self-test
  - Built-in firmware (ROM)
  - Self-Contained on chip calibration system

- Host Interface
  - UART
  - CAN-FD
  - SPI
  - LIN
- RDIF (Radar Data Interface) for raw ADC sample
- Other interfaces available to user application
  - QSPI
  - I2C
  - JTAG
  - GPIOs
  - PWM Interface
- **Internal Memory** 
  - 1MB of On-Chip RAM
  - Configurable L3 shared memory for Radar Cube
  - Data and Code RAM of (512/640/768KB)
- **Functional Safety-Compliant Targeted** 
  - Developed for Functional Safety Applications
  - Hardware integrity up to ASIL B targeted
- FCCSP package with 12 x 12, 102 BGA balls
- AEC Q-100 Qualified
- Clock source
  - 40.0MHz Crystal for primary clock
  - Supports externally driven clock (Square/Sine) at 40.0MHz
  - 32kHz internal oscillator for low power operations
- Supports temperature operating range
  - Operating Junction Temperature Range: –40°C to 125°C



### 2 Applications

- Kick to Open(Boot)
- Automated Parking
- Car Door Opener
- Cross-traffic Assist(Front)
- Blind Spot Detection
- Lane Change Assist

### 3 Description

The AWRL1432 mmWave Sensor device is an integrated single chip mmWave sensor based on FMCW radar technology. The device is capable of operation in the 76GHz to 81GHz band and is partitioned into mainly four power domains:

- **RF/Analog Sub-System**: This block includes all the RF and Analog components required to transmit and receive the RF signals.
- Front-End Controller sub-System (FECSS): FECSS contains processor, responsible for radar front-end configuration, control, and calibration.
- Application Sub-System (APPSS): APPSS is where the device implements a user programmable ARM Cortex M4 allowing for custom control and automotive interface applications. Top Sub-System (TOPSS) is part of the APPSS power domain and contains the clocking and power management sub-blocks.
- Hardware Accelerator (HWA): HWA block supplements the APPSS by offloading common radar processing such as FFT, Constant False Alarm rate (CFAR), scaling, and compression.

AWRL1432 is specifically designed to have separate controls for each of the above-mentioned power domains to control their states (power ON or OFF) based on use case requirements. The device also features the capability to exercise various low-power states like sleep and deep sleep, where low-power sleep mode is achieved by clock gating and by turning off the internal IP blocks of the device. The device also provides the option of keeping some contents of the device, like Application image or RF profile retained in such scenarios.

Additionally, the device is built with TI's low power 45nm RF CMOS process and enables unprecedented levels of integration in an extremely small form factor. AWRL1432 is designed for low power, self-monitored, ultra-accurate radar systems in the automotive space for applications like blind spot detection, kick-to-open, parking assist, and door obstacle detection.

### **Packaging Information**

| PART NUMBER <sup>(1)</sup> | PACKAGE          | BODY SIZE(2)    | TRAY / TAPE<br>AND REEL | DESCRIPTION  |
|----------------------------|------------------|-----------------|-------------------------|--|
| AWRL1432BDBGAMFRQ1         | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tape and Reel           | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. High quantity.                     |
| AWRL1432BDBGAMFQ1          | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tray                    | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. Low quantity.                      |
| AWRL1432BDBAAMFRQ1         | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tape and Reel           | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. Authenticated Boot. High quantity. |
| AWRL1432BDBAAMFQ1          | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tray                    | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. Authenticated Boot. Low quantity.  |
| AWRL1432BBAAMFRQ1          | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tape and Reel           | Automotive production variant. ASIL-B targeted. Authenticated Boot. High quantity.                     |



**Packaging Information (continued)** 

| PART NUMBER <sup>(1)</sup> | PACKAGE          | BODY SIZE(2)    | TRAY / TAPE<br>AND REEL | DESCRIPTION  |
|----------------------------|------------------|-----------------|-------------------------|--|
| AWRL1422BDBAAMFRQ1         | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tape and Reel           | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. Authenticated Boot. High quantity. |
| AWRL1422BDBGAMFRQ1         | AMF (FCCSP, 102) | 6.45mm x 6.45mm | Tape and Reel           | Automotive production variant. ASIL-B targeted. Deep Sleep enabled. High quantity.                     |

<sup>(1)</sup> (2) For more information, see Section 13

For more information, see , Section 11.1



## **4 Functional Block Diagram**

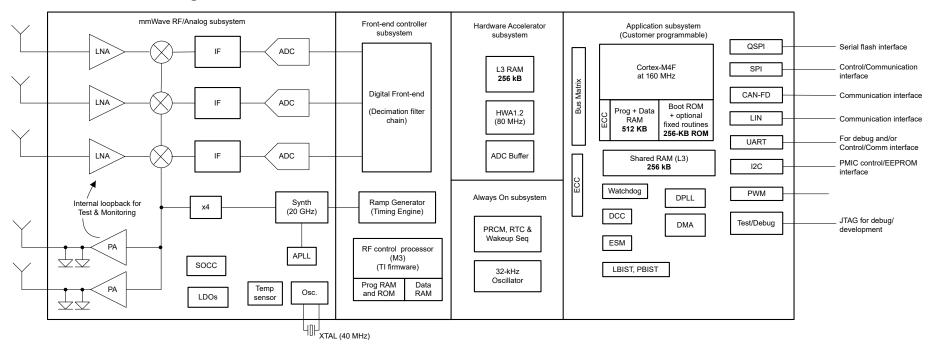


Figure 4-1. Functional Block Diagram



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## **5 Device Comparison**

The following table compares the features of radar devices.

**Table 5-1. Device Features Comparison** 

|  |                                | . Device Feature               |                    |                    |                   |
|--|--------------------------------|--------------------------------|--------------------|--------------------|-------------------|
| FUNCTION   | AWRL1432                       | AWRL6432                       | AWR1843AOP (1)     | AWR1843 (1)        | AWR1642           |
| Antenna on Package (AOP)   | -                              | -                              | Yes                | -                  | -                 |
| Number of receivers  | 3                              | 3                              | 4                  | 4                  | 4                 |
| Number of transmitters   | 2                              | 2                              | 3 <sup>(2)</sup>   | 3 <sup>(2)</sup>   | 2                 |
| RF frequency range   | 76 to 81 GHz                   | 57 to 64 GHz                   | 76 to 81 GHz       | 76 to 81 GHz       | 76 to 81 GHz      |
| On-chip memory   | 1 MB                           | 1 MB                           | 2MB                | 2MB                | 1.5MB             |
| Max I/F (Intermediate Frequency) (MHz)   | 5                              | 5                              | 10                 | 10                 | 5                 |
| Max real sampling rate (Msps)  | 12.5                           | 12.5                           | 25                 | 25                 | 12.5              |
| Max complex sampling rate (Msps)   | -                              | -                              | 12.5               | 12.5               | 6.25              |
| Safety and Security  |                                |                                |                    |                    | -                 |
| Functional Safety -Compliance  | ASIL-B Targeted <sup>(6)</sup> | ASIL-B Targeted <sup>(6)</sup> | ASIL-B             | ASIL-B             | ASIL-B            |
| Device Security <sup>(3)</sup>   | -                              | -                              | Yes                | Yes                | Yes               |
| Processors   |                                |                                |                    |                    |                   |
| MCU  | M4F                            | M4F                            | R4F                | R4F                | R4F               |
| DSP  | -                              | -                              | C674x              | C674x              | C674x             |
| HWA  | Yes                            | Yes                            | Yes                | Yes                | -                 |
| Peripherals  |                                |                                |                    |                    |                   |
| Serial Peripheral Interface (SPI) ports  | 2                              | 2                              | 2                  | 2                  | 2                 |
| Quad Serial Peripheral Interface (QSPI)  | Yes                            | Yes                            | Yes                | Yes                | Yes               |
| Inter-Integrated Circuit (I2C) interface   | 1                              | 1                              | 1                  | 1                  | 1                 |
| Controller Area Network<br>(Classical CAN) interface                                   | -                              | -                              | 1                  | 1                  | 1                 |
| Controller Area Network (CAN-FD) interface   | 1                              | 1                              | 1                  | 1                  | -                 |
| DSP Trace  | -                              | -                              | Yes                | Yes                | Yes               |
| PWM  | Yes                            | Yes                            | Yes                | Yes                | Yes               |
| DMM Interface  | -                              | -                              | Yes                | Yes                | Yes               |
| Hardware In Loop (HIL/DMM)   | -                              | -                              | Yes                | Yes                | Yes               |
| GPADC  | Yes                            | Yes                            | Yes                | Yes                | Yes               |
| ADC Raw Data Capture   | RDIF                           | RDIF                           | LVDS               | LVDS               | LVDS              |
| LIN  | Yes                            | Yes                            | -                  | -                  | -                 |
| UART   | 2                              | 2                              | 2                  | 2                  | 2                 |
| 1-V bypass mode  | N/A                            | N/A                            | Yes                | Yes                | Yes               |
| JTAG   | Yes                            | Yes                            | Yes                | Yes                | Yes               |
| Per Chirp configurable TX phase shifter  | BPM Only                       | BPM Only                       | Yes <sup>(4)</sup> | Yes <sup>(4)</sup> | BPM only          |
| Product Product Preview (PP), status Advance Information (AI), or Production Data (PD) | PD <sup>(5)</sup>              | PD <sup>(5)</sup>              | PD <sup>(5)</sup>  | PD <sup>(5)</sup>  | PD <sup>(5)</sup> |

<sup>(1)</sup> Developed for Functional Safety applications, the device supports hardware integrity up to ASIL-B. Refer to the related documentation for more details. Non-Functional Safety Variants are also available for AWRL1432 device.

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- (2) 3 Tx Simultaneous operation is supported only with 1-V LDO bypass and PA LDO disable mode. In this mode, the 1-V supply needs to be fed on the VOUT PA pin.
- (3) Device security features including Secure Boot and Customer Programmable Keys are available in select devices for only select part variants as indicated by the Device Type identifier in Section 3, Device Information table.
- (4) 6 bits linear Phase Shifter.
- (5) PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty.
- (6) As the certification can get secured at different times and post certificate the target will be updated to "compliant" from "compliance targeted" only in related data sheets, please refer to the respective data sheets for most recent compliance status.

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#### 5.1 Related Products

For information about other devices in this family of products or related products see the links that follow.

mmWave Sensors

TI's mmWave sensors rapidly and accurately sense range, angle and velocity with less power using the smallest footprint mmWave sensor portfolio for automotive applications.

**Automotive** mmWave Sensors TI's automotive mmWave sensor portfolio offers high-performance radar front end to ultra-high resolution, small and low-power single-chip radar solutions. Tl's scalable sensor portfolio enables design and development of ADAS system solution for every performance, application and sensor configuration ranging from comfort functions to safety functions in all vehicles.

for AWRL1432

Companion Products Review products that are similar to this product.

Reference designs for AWRL1432

TI Designs Reference Design Library is a robust reference design library spanning analog, embedded processor and connectivity. Created by TI experts to help you jumpstart your system design, all TI Designs include schematic or block diagrams, BOMs, and design files to speed your time to market. Search and download designs at ti.com/ tidesians.

Obstacle detection reference design

This reference design demonstrates the use of the AWRL1432/AWR1642 single-chip mmWave sensor with integrated DSP as an obstacle-detection sensor for the car door and trunk, enabling applications like automatic car door openers and intelligent car doors that can accurately detect obstacles/objects in a wide field of view (FoV).

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## **6 Terminal Configurations and Functions**

## **6.1 Pin Diagrams**

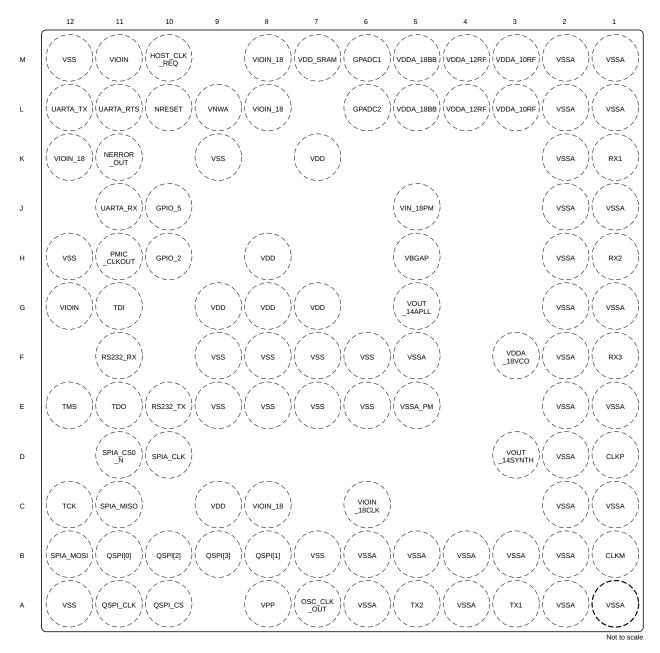


Figure 6-1. BGA Pin Diagram (Top View)

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### **6.2 Signal Descriptions**

#### Note

All digital IO pins of the device (except NRESET) are non-failsafe; hence, care needs to be taken that they are not driven externally without the VIO supply being present to the device.

**Table 6-1. Analog Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION             | BGA PIN |
|-------------|----------|-------------------------|---------|
| CLKM        | А        | XTAL CLKM pin           | B1      |
| CLKP        | Α        | XTAL CLKP pin           | D1      |
| GPADC1      | Α        | GPADC input 1           | M6      |
| GPADC2      | Α        | GPADC input 2           | L6      |
| NRESET      | Α        | NRESET input            | L10     |
| OSC_CLK_OUT | Α        | Oscillator Clock output | A7      |
| RX1         | Α        | RX channel 1            | K1      |
| RX2         | Α        | RX channel 2            | H1      |
| RX3         | Α        | RX channel 3            | F1      |
| TX1         | Α        | TX channel 1            | A3      |
| TX2         | A        | TX channel 2            | A5      |
| VBGAP       | Α        | BandGap reference pin   | H5      |

**Table 6-2. CAN Signal Descriptions** 

| <u> </u>    |          |                   |         |  |  |
|-------------|----------|-------------------|---------|--|--|
| SIGNAL NAME | PIN TYPE | DESCRIPTION       | BGA PIN |  |  |
| CAN_FD_RX   | I        | CAN Receive Data  | J11     |  |  |
| CAN_FD_TX   | 0        | CAN Transmit Data | L12     |  |  |

**Table 6-3. Clock Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION       | BGA PIN                   |
|-------------|----------|-------------------|---------------------------|
| MCU_CLKOUT  | 0        | MCU clock output  | K11, M10                  |
| PMIC_CLKOUT | 0        | PMIC clock output | H11                       |
| RTC_CLK_IN  | I        | RTC clock input   | B8, E12, H10, K11,<br>L11 |

Table 6-4. EPWM Signal Descriptions

| SIGNAL NAME   | PIN TYPE | DESCRIPTION      | BGA PIN            |
|---------------|----------|------------------|--------------------|
| EPWMA         | 0        | EPWM Output A    | C11, D11, G11, L11 |
| EPWMB         | 0        | EPWM Output B    | B12, C12, D10, J10 |
| EPWM_SYNC_IN  | I        | EPWM Sync Input  | E10, E12, J10      |
| EPWM_SYNC_OUT | 0        | EPWM Sync output | E12                |

**Table 6-5. GPIO Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION                  | BGA PIN |
|-------------|----------|------------------------------|---------|
| GPIO_0      | Ю        | General Purpose Input/Output | B12     |
| GPIO_1      | Ю        | General Purpose Input/Output | C11     |
| GPIO_2      | Ю        | General Purpose Input/Output | H10     |
| GPIO_3      | Ю        | General Purpose Input/Output | J11     |
| GPIO_4      | Ю        | General Purpose Input/Output | K11     |
| GPIO_5      | Ю        | General Purpose Input/Output | J10     |

**Table 6-5. GPIO Signal Descriptions (continued)** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION                  | BGA PIN |
|-------------|----------|------------------------------|---------|
| GPIO_6      | Ю        | General Purpose Input/Output | L11     |
| GPIO_7      | Ю        | General Purpose Input/Output | M10     |

Table 6-6. I2C Signal Descriptions

| · · · · · · · · · · · · · · · · · · · |          |             |                            |  |
|---------------------------------------|----------|-------------|----------------------------|--|
| SIGNAL NAME                           | PIN TYPE | DESCRIPTION | BGA PIN                    |  |
| I2C_SCL                               | Ю        |             | B10, D10, E10, L12,<br>M10 |  |
| I2C_SDA                               | Ю        | I2C Data    | B9, D11, F11, H10,<br>J11  |  |

**Table 6-7. JTAG Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION                 | BGA PIN |
|-------------|----------|-----------------------------|---------|
| тск         | I        | JTAG Test Clock Input       | C12     |
| TDI         | I        | JTAG Test Data Input        | G11     |
| TDO         | 0        | JTAG Test Data Output       | E11     |
| TMS         | I        | JTAG Test Mode Select Input | E12     |

**Table 6-8. LIN Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION      | BGA PIN                    |  |
|-------------|----------|------------------|----------------------------|--|
| LIN_RX      | I        | LIN Receive Data | F11, H10, J10, J11         |  |
| LIN_TX      | 0        |                  | E10, H11, L11, L12,<br>M10 |  |

**Table 6-9. MDO Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION     | BGA PIN                   |
|-------------|----------|-----------------|---------------------------|
| MDO_CLK     | 0        | MDO Clock       | A11, D10, L11             |
| MDO_D0      | 0        | MDO data 0      | B11, C12, H10             |
| MDO_D1      | 0        | MDO data 1      | B10, B12, E10, J11        |
| MDO_D2      | 0        | MDO data 2      | B9, C11, F11, L12         |
| MDO_D3      | 0        |                 | B8, D11, J10, K11,<br>M10 |
| MDO_FRM_CLK | 0        | MDO Frame Clock | A10, E11, H11, M10        |

**Table 6-10. Power Supply Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION        | BGA PIN                   |
|-------------|----------|--------------------|---------------------------|
| VDD         | PWR      | 1.2V Core supply   | C9, G7, G8, G9, H8,<br>K7 |
| VDDA_10RF   | PWR      | 1.0V RF Supply     | L3, M3                    |
| VDDA_12RF   | PWR      | 1.2V RF Supply     | L4, M4                    |
| VDDA_18BB   | PWR      | 1.8V analog supply | L5, M5                    |
| VDDA_18VCO  | PWR      | 1.8V analog supply | F3                        |
| VDD_SRAM    | PWR      | 1.2V SRAM supply   | M7                        |
| VIN_18PM    | PWR      | 1.8V core supply   | J5                        |
| VIOIN       | PWR      | 1.8V analog supply | G12, M11                  |
| VIOIN_18    | PWR      | 1.8V analog supply | C8, K12, L8, M8           |
| VIOIN_18CLK | PWR      | 1.8V analog supply | C6                        |
| VNWA        | PWR      | 1.2V VNWA supply   | L9                        |



**Table 6-10. Power Supply Signal Descriptions (continued)** 

| SIGNAL NAME  | PIN TYPE | DESCRIPTION        | BGA PIN   |
|--------------|----------|--------------------|---|
| VOUT_14APLL  | PWR      | 1.4V analog supply | G5  |
| VOUT_14SYNTH | PWR      | 1.4V analog supply | D3  |
| VPP          | PWR      | 1.8V VPP supply    | A8  |
| VSS          | GND      | Ground             | A12, B7, E6, E7, E8,<br>E9, F6, F7, F8, F9,<br>H12, K9, M12   |
| VSSA         | GND      | Ground             | A1, A2, A4, A6, B2,<br>B3, B4, B5, B6, C1,<br>C2, D2, E1, E2, F2,<br>F5, G1, G2, H2, J1,<br>J2, K2, L1, L2, M1,<br>M2 |
| VSSA_PM      | GND      | Ground             | E5  |

**Table 6-11. QSPI Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION      | BGA PIN |
|-------------|----------|------------------|---------|
| QSPI[0]     | Ю        | QSPI Data bit 0  | B11     |
| QSPI[1]     | I        | QSPI Data bit 1  | B8      |
| QSPI[2]     | I        | QSPI Data bit 2  | B10     |
| QSPI[3]     | I        | QSPI Data bit 3  | B9      |
| QSPI_CLK    | Ю        | QSPI Clock       | A11     |
| QSPI_CS     | 0        | OSPI Chip Select | A10     |

Table 6-12. RS232 Signal Descriptions

| SIGNAL NAME | PIN TYPE | DESCRIPTION         | BGA PIN |
|-------------|----------|---------------------|---------|
| RS232_RX    | I        | RS232 Receive Data  | F11     |
| RS232_TX    | 0        | RS232 Transmit Data | E10     |

**Table 6-13. SPIA Signal Descriptions** 

| SIGNAL NAME | PIN TYPE | DESCRIPTION        | BGA PIN       |
|-------------|----------|--------------------|---------------|
| SPIA_CLK    | Ю        | SPIA Clock         | D10           |
| SPIA_CS0_N  | Ю        | SPIA Chip Select 0 | D11           |
| SPIA_CS1_N  | Ю        | SPIA Chip Select 1 | E12, H10, H11 |
| SPIA_MISO   | Ю        | SPIA MISO          | C11           |
| SPIA_MOSI   | Ю        | SPIA MOSI          | B12           |

Table 6-14. SPIB Signal Descriptions

| Table of 141 of 12 digital 2000 inputorio |          |                    |                           |  |
|---|----------|--------------------|---------------------------|--|
| SIGNAL NAME                               | PIN TYPE | DESCRIPTION        | BGA PIN                   |  |
| SPIB_CLK                                  | Ю        | SPIB Clock         | A11, D10, E12, L11        |  |
| SPIB_CS0_N                                | Ю        | SPIB Chip Select 0 | A10, D11, G11, K11        |  |
| SPIB_CS1_N                                | Ю        | SPIB Chip Select 1 | C12, E10                  |  |
| SPIB_MISO                                 | Ю        | SPIB MISO          | B8, C11, E12, F11,<br>M10 |  |
| SPIB_MOSI                                 | Ю        | SPIB MOSI          | B11, B12, C12, L12        |  |

**Table 6-15. System Signal Descriptions** 

| SIGNAL NAME  | PIN TYPE | DESCRIPTION               | BGA PIN |
|--------------|----------|---------------------------|---------|
| HOST_CLK_REQ | 0        | Host clock request output | M10     |



Table 6-15. System Signal Descriptions (continued)

| rante o rei o jetem e gran e ee rip none (commune) |          |                      |                                 |  |
|--|----------|----------------------|---------------------------------|--|
| SIGNAL NAME  | PIN TYPE | DESCRIPTION          | BGA PIN                         |  |
| NERROR_OUT   | 0        | NERROR output signal | K11                             |  |
| SYNC_IN  | I        | Sync input           | B9, E12, J10, J11,<br>K11       |  |
| WARM_RESET_OUT                                     | 0        | Warm reset output    | E12, H10                        |  |
| WU_REQIN   | I        | , · · ·              | B10, H10, K11, L11,<br>L12, M10 |  |

### **Table 6-16. UARTA Signal Descriptions**

| SIGNAL NAME | PIN TYPE | DESCRIPTION         | BGA PIN |
|-------------|----------|---------------------|---------|
| UARTA_RTS   | 0        | UARTA RTS output    | L11     |
| UARTA_RX    | I        | UARTA Receive Data  | J11     |
| UARTA_TX    | 0        | UARTA Transmit Data | L12     |

## Table 6-17. UARTB Signal Descriptions

| SIGNAL NAME | PIN TYPE | DESCRIPTION         | BGA PIN  |
|-------------|----------|---------------------|----------|
| UARTB_RX    | I        | UARTB Receive Data  | F11, J11 |
| UARTB_TX    | 0        | UARTB Transmit Data | E10, L12 |

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Table 6-18. Pin Muxing Table

|                               |                          | Table 6-18. I              |                      | PIN CNTL                        |                     |                     | BALL                                    | BALL                                    |   |
|-------------------------------|--------------------------|----------------------------|----------------------|---------------------------------|---------------------|---------------------|---|---|---|
| BALL<br>NUMBER <sup>(1)</sup> | BALL NAME <sup>(2)</sup> | SIGNAL NAME <sup>(3)</sup> | PIN CNTL<br>REGISTER | REGISTER<br>ADDRESS<br>(5) (11) | MODE <sup>(6)</sup> | TYPE <sup>(7)</sup> | STATE<br>DURING<br>RESET <sup>(9)</sup> | STATE<br>AFTER<br>RESET <sup>(10)</sup> | PULL UP/<br>DOWN<br>TYPE <sup>(8)</sup> |
| H10                           | GPIO_2                   | GPIO_2                     | PADAL_CF             | 0x5A00                          | 0                   | Ю                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | LIN_RX                     | G_REG                | 002C                            | 1                   | I                   | Off                                     | Off                                     |   |
|                               |                          | WARM_RESET_OUT             |                      |                                 | 2                   | 0                   |   |   |   |
|                               |                          | I2C_SDA                    |                      |                                 | 3                   | Ю                   |   |   |   |
|                               |                          | SPIA_CS1_N                 |                      |                                 | 4                   | Ю                   |   |   |   |
|                               |                          | WU_REQIN                   |                      |                                 | 5                   | I                   |   |   |   |
|                               |                          | RTC_CLK_IN                 |                      |                                 | 6                   | I                   |   |   |   |
|                               |                          | MDO_D0                     |                      |                                 | 7                   | 0                   |   |   |   |
| J10                           | GPIO_5                   | GPIO_5                     | PADAV_CF<br>G_REG    | 0x5A00<br>0054                  | 0                   | Ю                   | Off / Off /<br>Off                      | Off / Off /<br>Off                      | PU/PD                                   |
|                               |                          | SYNC_IN                    | G_KEG                | 0034                            | 1                   | I                   |   | Oii                                     |   |
|                               |                          | LIN_RX                     |                      |                                 | 2                   | I                   |   |   |   |
|                               |                          | EPWMB                      |                      |                                 | 3                   | 0                   |   |   |   |
|                               |                          | EPWM_SYNC_IN               |                      |                                 | 4                   | I                   |   |   |   |
|                               |                          | MDO_D3                     |                      |                                 | 5                   | 0                   |   |   |   |
| M10                           | HOST_CLK_REQ             | HOST_CLK_REQ               | PADAX_CF             |                                 | 0                   | 0                   | Off / Off /                             | Off / SS /                              | PU/PD                                   |
|                               |                          | GPIO_7                     | G_REG                | 005C                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          | MCU_CLKOUT                 |                      |                                 | 2                   | 0                   |   |   |   |
|                               |                          | LIN_TX                     |                      |                                 | 3                   | 0                   |   |   |   |
|                               |                          | WU_REQIN                   |                      |                                 | 4                   | I                   |   |   |   |
|                               |                          | SPIB_MISO                  |                      |                                 | 5                   | Ю                   |   |   |   |
|                               |                          | I2C_SCL                    |                      |                                 | 6                   | Ю                   | 1                                       |   |   |
|                               |                          | MDO_D3                     |                      |                                 | 8                   | 0                   |   |   |   |
|                               |                          | MDO_FRM_CLK                |                      |                                 | 9                   | 0                   | 1                                       |   |   |
| K11                           | NERROR_OUT               | NERROR_OUT                 | PADAU_C              | 0x5A00                          | 0                   | 0                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | GPIO_4                     | FG_REG               | 0050                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          | SYNC_IN                    |                      |                                 | 2                   | ı                   | 1                                       |   |   |
|                               |                          | SPIB_CS0_N                 |                      |                                 | 3                   | Ю                   | 1                                       |   |   |
|                               |                          | WU_REQIN                   |                      |                                 | 4                   | ı                   | 1                                       |   |   |
|                               |                          | RTC_CLK_IN                 |                      |                                 | 5                   | ı                   | 1                                       |   |   |
|                               |                          | MCU_CLKOUT                 |                      |                                 | 6                   | 0                   | 1                                       |   |   |
|                               |                          | MDO_D3                     |                      |                                 | 7                   | 0                   | 1                                       |   |   |
| H11                           | PMIC_CLKOUT              | SOP[1]                     | PADAK_CF<br>G_REG    | 0x5A00<br>0028                  | During<br>Power-up  | I                   | Off / Off /<br>Off                      | Off / Off /<br>Off                      | PU/PD                                   |
|                               |                          | PMIC_CLKOUT                |                      |                                 | 0                   | 0                   |   |   |   |
|                               |                          | LIN_TX                     |                      |                                 | 1                   | 0                   | 1                                       |   |   |
|                               |                          | SPIA_CS1_N                 |                      |                                 | 2                   | Ю                   | 1                                       |   |   |
|                               |                          | MDO_FRM_CLK                |                      |                                 | 3                   | 0                   | 1                                       |   |   |
| B11                           | QSPI[0]                  | QSPI[0]                    | PADAC_C              | 0x5A00                          | 0                   | Ю                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | SPIB_MOSI                  | FG_REG               | 8000                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          | MDO_D0                     |                      |                                 | 2                   | 0                   | 1                                       |   |   |
| B8                            | QSPI[1]                  | QSPI[1]                    | PADAD_C              | 0x5A00                          | 0                   | ı                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | SPIB_MISO                  | FG_REG               | 000C                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          | RTC_CLK_IN                 |                      |                                 | 2                   | ı                   | 1                                       |   |   |
|                               |                          | MDO_D3                     |                      |                                 | 3                   | 0                   | 1                                       |   |   |
| B10                           | QSPI[2]                  | QSPI[2]                    | PADAE_CF             |                                 | 0                   | ı                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | I2C_SCL                    | G_REG                | 0010                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          | WU_REQIN                   |                      |                                 | 2                   | 1                   | 1                                       |   |   |
|                               |                          | MDO_D1                     |                      |                                 | 3                   | 0                   | 1                                       |   |   |
| B9                            | QSPI[3]                  | QSPI[3]                    | PADAF_CF             | 0x5A00                          | 0                   | I                   | Off / Off /                             | Off / Off /                             | PU/PD                                   |
|                               |                          | I2C_SDA                    | G_REG                | 0014                            | 1                   | Ю                   | Off                                     | Off                                     |   |
|                               |                          |                            |                      | 1                               |                     |                     | -                                       | 1                                       | 1                                       |
|                               |                          | SYNC_IN                    |                      |                                 | 2                   | 1                   |   |   |   |

### **Table 6-18. Pin Muxing Table (continued)**

| BALL<br>NUMBER <sup>(1)</sup> | BALL NAME <sup>(2)</sup> | SIGNAL NAME <sup>(3)</sup> | PIN CNTL<br>REGISTER | PIN CNTL<br>REGISTER<br>ADDRESS<br>(5) (11) | MODE <sup>(6)</sup> | TYPE <sup>(7)</sup> | BALL<br>STATE<br>DURING<br>RESET <sup>(9)</sup> | BALL<br>STATE<br>AFTER<br>RESET <sup>(10)</sup> | PULL UP/<br>DOWN<br>TYPE <sup>(8)</sup> |       |
|-------------------------------|--------------------------|----------------------------|----------------------|---|---------------------|---------------------|---|---|---|-------|
| A11                           | QSPI_CLK                 | QSPI_CLK                   | PADAA_CF             |   | 0                   | Ю                   | Off / Off /                                     | Off / Off /                                     | PU/PD                                   |       |
|                               |                          | SPIB_CLK                   | G_REG                | 0000  | 1                   | Ю                   | Off   | Off   |   |       |
|                               |                          | MDO_CLK                    |                      |   | 2                   | 0                   |   |   |   |       |
| A10                           | QSPI_CS                  | QSPI_CS                    | PADAB_CF             |   | 0                   | 0                   | Off / Off /                                     | Off / Off /                                     | PU/PD                                   |       |
|                               |                          | SPIB_CS0_N                 | G_REG                | 0004  | 1                   | Ю                   | Off   | Off   |   |       |
|                               |                          | MDO_FRM_CLK                |                      |   | 2                   | 0                   |   |   |   |       |
| F11                           | RS232_RX                 | RS232_RX                   | PADAP_CF             |   | 0                   | 1                   | Off / Off /                                     | On / Off /                                      | PU/PD                                   |       |
|                               |                          | I2C_SDA                    | G_REG                | 003C  | 1                   | Ю                   | Up  | Up  |   |       |
|                               |                          | UARTB_RX                   |                      |   | 2                   | 1                   |   |   |   |       |
|                               |                          | LIN_RX                     |                      |   | 3                   | 1                   |   |   |   |       |
|                               |                          | MDO_D2                     |                      |   | 4                   | 0                   |   |   |   |       |
|                               |                          | SPIB_MISO                  |                      |   | 5                   | Ю                   |   |   |   |       |
| E10                           | RS232_TX                 | RS232_TX                   | PADAO_C              | 0x5A00                                      | 0                   | 0                   | Off / Off /                                     | Off / SS /                                      | PU/PD                                   |       |
|                               |                          | I2C_SCL                    | FG_REG               | 0038  | 1                   | Ю                   | Off   | Off   |   |       |
|                               |                          | UARTB_TX                   |                      |   | 2                   | 0                   |   |   |   |       |
|                               |                          | LIN_TX                     |                      |   | 3                   | 0                   |   |   |   |       |
|                               |                          | EPWM_SYNC_IN               |                      |   | 4                   | I                   |   |   |   |       |
|                               |                          | MDO_D1                     |                      |   | 5                   | 0                   |   |   |   |       |
|                               |                          | SPIB_CS1_N                 |                      |   | 6                   | Ю                   | 7   |   |   |       |
| D10                           | SPIA_CLK                 | SPIA_CLK                   | PADAG_C              | 0x5A00                                      | 0                   | Ю                   | Off / Off / Off / Off                           |   | Off / Off /                             | PU/PD |
|                               |                          | EPWMB                      | FG_REG               | 0018  | 1                   | 0                   |   | Off   |   |       |
|                               |                          | I2C_SCL                    |                      |   | 2                   | Ю                   |   |   |   |       |
|                               |                          | SPIB_CLK                   |                      |   | 3                   | Ю                   |   |   |   |       |
|                               |                          | MDO_CLK                    |                      |   | 4                   | 0                   |   |   |   |       |
| D11                           | SPIA_CS0_N               | SPIA_CS0_N                 | PADAH_C              | 0x5A00                                      | 0                   | Ю                   | Off / Off /                                     | Off / Off /<br>Off                              | PU/PD                                   |       |
|                               |                          | EPWMA                      | FG_REG               |   | 1                   | 0                   | Off O   |   |   |       |
|                               |                          | I2C_SDA                    |                      |   | 2                   | Ю                   |   |   |   |       |
|                               |                          | SPIB_CS0_N                 |                      |   | 3                   | Ю                   |   |   |   |       |
|                               |                          | MDO_D3                     |                      |   | 4                   | 0                   |   |   |   |       |
| C11                           | SPIA_MISO                | SPIA_MISO                  | PADAJ_CF             | 0x5A00                                      | 0                   | Ю                   | Off / Off /                                     | Off / Off /<br>Off                              | PU/PD                                   |       |
|                               |                          | GPIO_1                     | G_REG                | 0024  | 1                   | Ю                   | Off   |   |   |       |
|                               |                          | EPWMA                      |                      |   | 2                   | 0                   |   |   |   |       |
|                               |                          | SPIB_MISO                  |                      |   | 3                   | Ю                   | 7   |   |   |       |
|                               |                          | MDO_D2                     |                      |   | 4                   | 0                   |   |   |   |       |
| B12                           | SPIA_MOSI                | SPIA_MOSI                  | PADAI_CF             | 0x5A00                                      | 0                   | Ю                   | Off / Off /                                     | Off / Off /                                     | PU/PD                                   |       |
|                               |                          | GPIO_0                     | G_REG                | 0020  | 1                   | Ю                   | Off   | Off   |   |       |
|                               |                          | EPWMB                      |                      |   | 2                   | 0                   |   |   |   |       |
|                               |                          | SPIB_MOSI                  |                      |   | 3                   | Ю                   |   |   |   |       |
|                               |                          | MDO_D1                     |                      |   | 4                   | 0                   |   |   |   |       |
| C12                           | TCK                      | тск                        | PADAT_CF<br>G_REG    | 0x5A00                                      | 0                   | 1                   | Off / Off /                                     | On / Off /                                      | PU/PD                                   |       |
|                               |                          | EPWMB                      | G_REG                | 004C  | 1                   | 0                   | Down  | Down  |   |       |
|                               |                          | SPIB_CS1_N                 |                      |   | 2                   | Ю                   |   |   |   |       |
|                               |                          | SPIB_MOSI                  |                      |   | 3                   | Ю                   |   |   |   |       |
|                               |                          | MDO_D0                     |                      |   | 4                   | 0                   |   |   |   |       |
| G11                           | TDI                      | TDI                        | PADAR_C<br>FG_REG    | 0x5A00<br>0044                              | 0                   | I                   | Off / Off /<br>Down                             | On / Off /<br>Down                              | PU/PD                                   |       |
|                               |                          | EPWMA                      | 1.0_KEG              | 0044  | 1                   | 0                   | DOWII   | DOWII   |   |       |
|                               |                          | SPIB_CS0_N                 |                      |   | 2                   | Ю                   |   |   |   |       |
| E11                           | TDO                      | SOP[0]                     | PADAS_CF<br>G_REG    | 0x5A00<br>0048                              | During<br>Power-up  | I                   | Off / Off /<br>Off                              | Off / SS /<br>Off                               | PU/PD                                   |       |
|                               |                          | TDO                        |                      |   | 0                   | 0                   |   |   |   |       |
|                               |                          | MDO_FRM_CLK                |                      |   | 1                   | 0                   |   |   |   |       |

#### Table 6-18. Pin Muxing Table (continued)

| BALL<br>NUMBER <sup>(1)</sup> | BALL NAME <sup>(2)</sup> | SIGNAL NAME <sup>(3)</sup> | PIN CNTL<br>REGISTER | PIN CNTL<br>REGISTER<br>ADDRESS<br>(5) (11) | MODE <sup>(6)</sup> | TYPE <sup>(7)</sup> | BALL<br>STATE<br>DURING<br>RESET <sup>(9)</sup> | BALL<br>STATE<br>AFTER<br>RESET <sup>(10)</sup> | PULL UP/<br>DOWN<br>TYPE <sup>(8)</sup> |
|-------------------------------|--------------------------|----------------------------|----------------------|---|---------------------|---------------------|---|---|---|
| E12                           | TMS                      | TMS                        | PADAQ_C              | 0x5A00                                      | 0                   | 1                   | Off / Off /                                     | On / Off /<br>Up                                | PU/PD                                   |
|                               |                          | WARM_RESET_OUT             | FG_REG               | 0040  | 1                   | 0                   | Up  |   |   |
|                               |                          | SPIA_CS1_N                 |                      |   | 2                   | Ю                   |   |   |   |
|                               |                          | SYNC_IN                    |                      |   | 3                   | ı                   | 1   |   |   |
|                               |                          | SPIB_MISO                  |                      |   | 4                   | Ю                   | 1   |   |   |
|                               |                          | SPIB_CLK                   |                      |   | 5                   | Ю                   | 1   |   |   |
|                               |                          | RTC_CLK_IN                 |                      |   | 6                   | 1                   |   |   |   |
|                               |                          | EPWM_SYNC_IN               |                      |   | 7                   | I                   | 1   |   |   |
|                               |                          | EPWM_SYNC_OUT              |                      |   | 8                   | 0                   | 1   |   |   |
| L11                           | UARTA_RTS                | UARTA_RTS                  | PADAW_C              | 0x5A00                                      | 0                   | 0                   | Off / Off /                                     | Off / Off /                                     | PU/PD                                   |
|                               |                          | GPIO_6                     | FG_REG               | 0058  | 1                   | Ю                   | Off   | Off   |   |
|                               |                          | LIN_TX                     |                      |   | 2                   | 0                   |   |   |   |
|                               |                          | SPIB_CLK                   |                      |   | 3                   | Ю                   |   |   |   |
|                               |                          | WU_REQIN                   |                      |   | 4                   | I                   |   |   |   |
|                               |                          | EPWMA                      |                      |   | 5                   | 0                   |   |   |   |
|                               |                          | RTC_CLK_IN                 |                      |   | 6                   | I                   |   |   |   |
|                               |                          | MDO_CLK                    |                      |   | 7                   | 0                   |   |   |   |
| J11                           | UARTA_RX                 | UARTA_RX                   | PADAM_C              | 0x5A00<br>0030                              | 0                   | I                   | Off / Off /<br>Off                              | Off / Off /<br>Off                              | PU/PD                                   |
|                               |                          | GPIO_3                     | FG_REG               |   | 1                   | Ю                   |   |   |   |
|                               |                          | LIN_RX                     |                      |   | 2                   | I                   |   |   |   |
|                               |                          | CAN_FD_RX                  |                      |   | 3                   | ı                   | ]   |   |   |
|                               |                          | SYNC_IN                    |                      |   | 4                   | ı                   | 1   |   |   |
|                               |                          | UARTB_RX                   |                      |   | 5                   | I                   |   |   |   |
|                               |                          | I2C_SDA                    |                      |   | 6                   | Ю                   | 1   |   |   |
|                               |                          | MDO_D1                     |                      |   | 7                   | 0                   | ]   |   |   |
| L12                           | UARTA_TX                 | UARTA_TX                   | PADAN_C              | 0x5A00                                      | 0                   | 0                   | Off / Off /                                     | Off / Off /                                     | PU/PD                                   |
|                               |                          | LIN_TX                     | FG_REG               | 0034  | 1                   | 0                   | Off   | Off   |   |
|                               |                          | CAN_FD_TX                  |                      |   | 2                   | 0                   |   |   |   |
|                               |                          | SPIB_MOSI                  |                      |   | 3                   | Ю                   |   |   |   |
|                               |                          | WU_REQIN                   |                      |   | 4                   | I                   |   |   |   |
|                               |                          | UARTB_TX                   |                      |   | 5                   | 0                   |   |   |   |
|                               |                          | I2C_SCL                    |                      |   | 6                   | Ю                   | 1   |   |   |
|                               |                          | MDO_D2                     |                      |   | 7                   | 0                   | 1   |   |   |

- (1) BALL NUMBER: Ball numbers on the bottom side associated with each signal on the bottom.
- (2) BALL NAME: Mechanical name from package device (name is taken from muxmode 0).
- SIGNAL NAME: Names of signals multiplexed on each ball (also notice that the name of the ball is the signal name in muxmode 0). (3)
- PINCNTL\_REGISTER: APPSS Register name for PinMux Control (4)
- (5) PINCNTL ADDRESS: APPSS Address for PinMux Control
- MODE: Multiplexing mode number: value written to PinMux Cntl register to select specific Signal name for this Ball number. Mode column has bit range value.
- TYPE: Signal type and direction:
  - I = Input
  - O = Output
  - IO = Input or Output
- PULL UP/DOWN TYPE: indicates the presence of an internal pullup or pulldown resistor. Pullup and pulldown resistors can be (8) enabled or disabled via software.
  - Pull Up: Internal pullup
  - Pull Down: Internal pulldown
  - An empty box means No pull.
- BALL STATE DURING RST: State of Ball during reset in the format of RX/TX/Pull Status
  - RX (Input buffer)
    - Off: The input buffer is disabled.
    - On: The input buffer is enabled.



# TX (Output buffer)

- Off: The output buffer is disabled.
- Low: The output buffer is enabled and drives V<sub>OL</sub>.
- Pull Status (Internal pull resistors)
  - Off: Internal pull resistors are turned off.
  - Up: Internal pull-up resistor is turned on.
  - Down: Internal pull-down resistor is turned on.
  - NA: No internal pull resistor.
- · An empty box, or "-" means Not Applicable.

#### (10) BALL STATE AFTER RST: State of Ball after reset in the format of RX/TX/Pull Status

- RX (Input buffer)
  - Off: The input buffer is disabled.
  - On: The input buffer is enabled.
- TX (Output buffer)
  - Off: The output buffer is disabled.
  - SS: The subsystem selected with MUXMODE determines the output buffer state.
- Pull status (Internal pull resistors)
  - Off: Internal pull resistors are turned off.
  - Up: Internal pull-up resistor is turned on.
  - Down: Internal pull-down resistor is turned on.
  - NA: No internal pull resistor.
- An empty box, NA, or "-" means Not Applicable.
- (11) Pin Mux Control Value maps to lower 4 bits of register.



## 7 Specifications

### 7.1 Absolute Maximum Ratings

|                                | PARAMETERS <sup>(1)</sup> (2)   | MIN   | MAX                                 | UNIT |
|--------------------------------|---|-------|-------------------------------------|------|
| VDD                            | 1.2V digital power supply   | -0.5  | 1.4                                 | V    |
| VIOIN                          | I/O supply (3.3V or 1.8V): All CMOS I/Os operate on the same VIOIN voltage level  | -0.5  | 3.8                                 | V    |
| VIOIN_18                       | 1.8V supply for CMOS IO   | -0.5  | 2                                   | V    |
| VIOIN_18CLK                    | 1.8V supply for clock module  | -0.5  | 2                                   | V    |
| VDDA_18BB                      | 1.8V Analog baseband power supply   | -0.5  | 2                                   | V    |
| VDDA_18VCO supply              | 1.8V RF VCO supply  | -0.5  | 2                                   | V    |
| VPP                            | Voltage supply for fuse chain   | -0.5  | 2                                   | V    |
| RX1-3                          | Externally applied power on RF inputs   |       | 10                                  | dBm  |
| TX1-2                          | Externally applied power on RF outputs <sup>(3)</sup>   |       | 10                                  | dBm  |
| In most and asstance           | Dual-voltage LVCMOS inputs, 3.3V or 1.8V (Steady State)   | -0.3V | VIOIN + 0.3                         |      |
| Input and output voltage range | Dual-voltage LVCMOS inputs, operated at 3.3V/1.8V (Transient Overshoot/Undershoot) or external oscillator input   |       | OIN + 20% up to<br>of signal period | V    |
| CLKP, CLKM                     | Input ports for reference crystal   | -0.5  | 2                                   | V    |
| Clamp current                  | Input or Output Voltages 0.3V above or below their respective power rails. Limit clamp current that flows through the internal diode protection cells of the I/O. | -20   | 20                                  | mA   |
| T <sub>J</sub>                 | Operating junction temperature range  | -40   | 125                                 | °C   |
| T <sub>STG</sub>               | Storage temperature range after soldered onto PC board  | -55   | 150                                 | °C   |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to V<sub>SS</sub>, unless otherwise noted.

### 7.2 ESD Ratings

|                    |  |  |             | VALUE | UNIT |
|--------------------|--|--|-------------|-------|------|
|                    | Electrostatic  | Human-body model (HBM), per AECQ100-002 <sup>(1)</sup> | All pins    | ±2000 |      |
| V <sub>(ESD)</sub> | discharge Charged-device model (CDM), per AEC Q100-011 | All pins   | ±500        | V     |      |
|                    |  | Q100-011   | Corner pins | ±750  |      |

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 7.3 Power-On Hours (POH)

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| JUNCTION TEMPERATURE (T <sub>j</sub> ) | OPERATING<br>CONDITION | NOMINAL CVDD VOLTAGE (V) | POWER-ON HOURS [POH] (HOURS) |
|--|------------------------|--------------------------|------------------------------|
| -40°C                                  |                        |                          | 600 (6%)                     |
| 75°C                                   | 100% duty avala        | 1.2                      | 2000 (20%)                   |
| 95°C                                   | 100% duty cycle        |                          | 6500 (65%)                   |
| 125°C                                  |                        |                          | 900 (9%)                     |

<sup>(1)</sup> This information is provided solely for your convenience and does not extend or modify the warranty provided under TI's standard terms and conditions for TI semiconductor products.

<sup>(3)</sup> This value is for an externally applied signal level on the TX. Additionally, a reflection coefficient up to Gamma = 1 can be applied on the TX output.



### 7.4 Recommended Operating Conditions

|                    |  | MIN         | NOM               | MAX   | UNIT |  |
|--------------------|--|-------------|-------------------|-------|------|--|
| VDD                | 1.2 V digital power supply                           | 1.14        | 1.2               | 1.26  | V    |  |
| VIOIN              | I/O supply (3.3 V or 1.8 V):                         | 3.135       | 3.3               | 3.465 | V    |  |
| VIOIN              | All CMOS I/Os would operate on this supply.          | 1.71        | 1.8               | 1.89  | V    |  |
| VIOIN_18           | 1.8 V supply for CMOS IO                             | 1.71        | 1.8               | 1.89  | V    |  |
| VIOIN_18CLK        | 1.8 V supply for clock module                        | 1.71        | 1.8               | 1.89  | V    |  |
| VDDA_18BB          | 1.8-V Analog baseband power supply                   | 1.71        | 1.8               | 1.89  | V    |  |
| VDDA_18VCO         | 1.8V RF VCO supply                                   | 1.71        | 1.8               | 1.89  | V    |  |
|                    | Voltage Input High (1.8 V mode)                      | 1.17        |                   |       | V    |  |
| $V_{IH}$           | Voltage Input High (3.3 V mode)                      | 2.25        |                   |       | V    |  |
| V                  | Voltage Input Low (1.8 V mode)                       |             | 0.3*VIOIN<br>0.62 |       |      |  |
| V <sub>IL</sub>    | Voltage Input Low (3.3 V mode)                       |             |                   |       | V    |  |
| V <sub>OH</sub>    | High-level output threshold (I <sub>OH</sub> = 6 mA) | VIOIN – 450 |                   |       | mV   |  |
| V <sub>OL</sub>    | Low-level output threshold (I <sub>OL</sub> = 6 mA)  |             |                   | 450   | mV   |  |
|                    | V <sub>IL</sub> (1.8V Mode)                          |             |                   | 0.2   |      |  |
| NRESET<br>SOP[1:0] | V <sub>IH</sub> (1.8V Mode)                          | 0.96        |                   |       | .,   |  |
|                    | V <sub>IL</sub> (3.3V Mode)                          |             | 0.3               |       | V    |  |
|                    | V <sub>IH</sub> (3.3V Mode)                          | 1.57        |                   |       |      |  |

### 7.5 VPP Specifications for One-Time Programmable (OTP) eFuses

This section specifies the operating conditions required for programming the OTP eFuses and is applicable only for authenticated boot devices. During the process of writing the customer specific keys or other fields like software version etc. in the efuse, the user needs to provide the VPP supply.

### 7.5.1 Recommended Operating Conditions for OTP eFuse Programming

| PARAMETER       | DESCRIPTION   | MIN  | NOM               | MAX  | UNIT  |
|-----------------|---|------|-------------------|------|-------|
| VPP             | Supply voltage range for the eFuse ROM domain during normal operation               |      | NC <sup>(2)</sup> |      |       |
| VFF             | Supply voltage range for the eFuse ROM domain during OTP programming <sup>(1)</sup> | 1.65 | 1.7               | 1.75 | V     |
| Duration of VPP | If VPP voltage is supplied for more than recommended                                |      |                   | 24   | Hours |
| Supply          | Hours, it can cause reliability issue   |      |                   |      |       |
| I(VPP)          |   |      |                   | 50   | mA    |

<sup>(1)</sup> During normal operation, no voltage should be applied to VPP. This can be typically achieved by disabling the external regulator attached to the VPP terminal.

#### Note

Power up sequence: VPP must be ramped up at the end i.e after all other rails ramp up is done

#### 7.5.2 Hardware Requirements

The following hardware requirements must be met when programming keys in the OTP eFuses:

• The VPP power supply must be disabled when not programming OTP registers.

<sup>(2)</sup> NC: No Connect



### 7.5.3 Impact to Your Hardware Warranty

You recognize and accept at your own risk that your use of eFuse permanently alters the TI device. You acknowledge that eFuse can fail due to incorrect operating conditions or programming sequence. Such a failure may render the TI device inoperable and TI will be unable to confirm the TI device conformed to TI device specifications prior to the attempted eFuse. CONSEQUENTLY, in these cases of faulty EFUSE programmability, TI WILL HAVE NO LIABILITY.



#### 7.6 Power Supply Specifications

#### 7.6.1 Power Optimized 3.3V I/O Topology

Table 7-1 describes the power rails from an external power supply block to the device via a 3.3V I/O topology.

Table 7-1. Power Supply Rails Characteristics: Power Optimized 3.3V I/O Topology

| SUPPLY | DEVICE BLOCKS POWERED FROM THE SUPPLY                                   | RELEVANT IOS IN THE DEVICE  |
|--------|---|---|
| 3.3 V  | Digital I/Os  | Input: VIOIN  |
| 1.8 V  | Synthesizer and APLL VCOs, crystal oscillator, IF Amplifier stages, ADC | Input: VDDA_18VCO, VIOIN_18CLK, VDDA_18BB, VIOIN_18, VIN_18PM LDO Output: VOUT_14SYNTH, VOUT_14APLL |
| 1.2 V  | Core Digital and SRAMs, RF  | Input: VDD, VNWA, VDD_SRAM, VDDA_12RF<br>LDO Output: VDDA_10RF                                      |

#### 7.6.2 BOM Optimized 3.3V I/O Topology

Table 7-2 describes the power rails from an external power supply block to the device via a BOM Optimized 3.3V I/O Topology.

Table 7-2. Power Supply Rails Characteristics: BOM Optimized 3.3V I/O Topology

| SUPPLY | DEVICE BLOCKS POWERED FROM THE SUPPLY                                   | RELEVANT IOS IN THE DEVICE   |
|--------|---|--|
| 3.3V   | Digital I/Os  | Input: VIOIN   |
| 1.8V   | Synthesizer and APLL VCOs, crystal oscillator, IF Amplifier stages, ADC | Input: VDDA_18VCO, VIOIN_18CLK, VDDA_18BB, VIOIN_18, VIN_18PM LDO Output: VOUT_14SYNTH, VDDA_10RF, VDD_SRAM, VNWA, VOUT_14APLL, VDDA_12RF, VDD |

#### 7.6.3 Power Optimized 1.8V I/O Topology

Table 7-3 describes the power rails from an external power supply block to the device via a power optimized 1.8V I/O topology.

Table 7-3. Power Supply Rails Characteristics: Power Optimized 1.8V I/O Topology

| 3)     |                                       |  |  |  |  |  |
|--------|---------------------------------------|--|--|--|--|--|
| SUPPLY | DEVICE BLOCKS POWERED FROM THE SUPPLY | RELEVANT IOS IN THE DEVICE   |  |  |  |  |
| 1.8 V  | Amplifier stages ADC                  | Input: VIOIN, VIN_18PM, VDDA_18VCO,<br>VIOIN_18CLK, VDDA_18BB, VIOIN_18<br>LDO Output: VOUT_14SYNTH, VOUT_14APLL |  |  |  |  |
| 1.2 V  | Core Digital and SRAMs, RF, VNWA      | Input: VDD, VDD_SRAM, VNWA,VDDA_12RF<br>LDO Output: VDDA_10RF  |  |  |  |  |

#### 7.6.4 BOM Optimized 1.8V I/O Topology

Table 7-4 describes the power rails from an external power supply block to the device via a BOM optimized 1.8V I/O topology.

Table 7-4. Power Supply Rails Characteristics: BOM Optimized 1.8V I/O Topology

| SUPPLY | DEVICE BLOCKS POWERED FROM THE SUPPLY  | RELEVANT IOS IN THE DEVICE  |
|--------|--|---|
| 1.8 V  | Synthesizer and APLL VCOs, crystal oscillator, IF<br>Amplifier stages, ADC, Digital I/Os | Input: VIOIN, VDDA_18VCO, VIOIN_18CLK, VIOIN_18, VDDA_18BB, VIN_18PM, VDDA_18VCO LDO Output: VDD, VDD_SRAM, VNWA, VDDA_10RF, VDDA_12RF, VOUT_14APLL, VOUT_14SYNTH |

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#### 7.6.5 System Topologies

The following the system topologies are supported.

- Topology 1: Peripheral Mode, under the control of external MCU
- Topology 2: Autonomous mode, with connection to a remote host via LIN/CAN

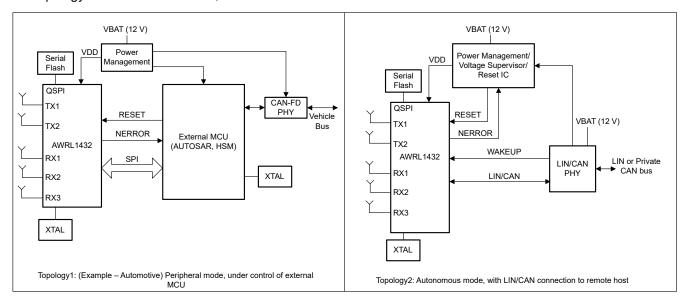


Figure 7-1. System Topologies

In Topology 1: Peripheral mode, the AWRL1432 is controlled by external MCU and most of the processing is done on *external* MCU. In this case, the computational and power requirements are relatively higher and the external MCU can stay active most of the time.

In Topology 2: Autonomous mode, the AWRL1432 can be used as full sensor along with M4F application processor. In this case the internal application processor does all the processing and interrupts the host processor to communicate to take action based on the sensor data. Most of the processing happens on the *internal* MCU of the AWRL1432 chip and only high level desired results are communicated to external host via LIN/CAN.

#### 7.6.5.1 Power Topologies

The device supports two unique power topologies for BOM optimized and Power Optimized modes. Above tables summarizes these options. Based on whether the 1.2V rail is generated internally or is provided from external source, two power topologies comes into account.

In BOM optimized mode the device can be powered up using one rail (1.8V) or two rails (3.3V and a 1.8V) provided externally. The 1.2V rail is internally generated in BOM optimized topology.

In power optimized mode, the device can either be powered using two rails (1.8V and 1.2V) or with three rails (3.3V, 1.8V and 1.2V), all provided externally. The 1.2V rail is NOT internally generated in Power optimized topology. The device senses the external 1.2V supply and decides which topology the device will operate on.

### 7.6.5.1.1 BOM Optimized Mode

In this mode the device can be powered using one 1.8V regulator OR using a 3.3V and a 1.8V regulator mode. The choice of one rail vs two rails is dependent on the IO voltages needed.

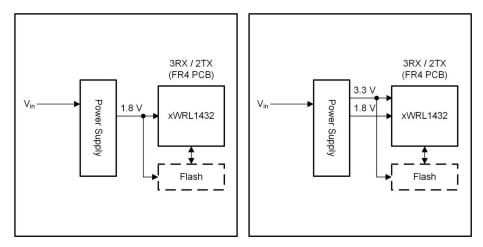


Figure 7-2. BOM Optimized Mode Power Management (Left: 1.8V I/O Topology, Right: 3.3V I/O Topology)

### 7.6.5.1.2 Power Optimized Mode

This mode is for applications needing ultra-low power applications. The device can either be powered using two rails (1.8 V and 1.2 V) or with three rails (3.3 V, 1.8 V and 1.2 V).

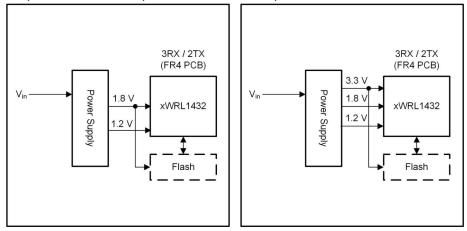


Figure 7-3. Power Optimized Mode Power Management (Left: 1.8V I/O Topology, Right: 3.3V I/O Topology)

### 7.6.6 Internal LDO output decoupling capacitor and layout conditions for BOM optimized topology

This section depicts the recommended values of de-coupling capacitors and range of allowable parasitic inductance and resistance in particular sections of the output path for the internal LDOs. Like all low dropout regulators, the internal LDO requires an output capacitor connected between OUTPUT and GND to stabilize the internal control loop. We recommended to use X7R type capacitors which has a lower variation across temperature. The minimum and maximum values of the capacitor captured in below table. The table includes variation of a given capacitor due to DC bias, tolerance and temperature variation.

### Note

- 1. If the parasitic values are not kept within the specified range, performance of the device can degrade.
- Typical values of de-coupling capacitors are recommended to use. Any capacitance value taken near the edge of the range can degrade the performance. The working range of the chosen capacitor can not exceed the specified range.

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### 7.6.6.1 Single-capacitor rail

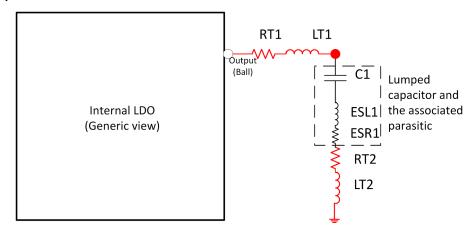


Figure 7-4. Parasitic offered by different portion of the output path (for one capacitor)

1.2V Digital LDO requires one decoupling capacitor with a typical value of 4.7uF. The parasitic offered by different portion of the output path is illustrated in Figure 7-4. "RT1" and "RT2" are parasitic resistances offered by the ball to capacitor lead trace and the ground trace respectively. Similarly, "LT1" and "LT2" are parasitic inductances offered by the ball to capacitor lead trace and the ground trace respectively. "ESL1" and "ESR1" are the effective series inductance and resistance of the decoupling capacitor. Section 7.6.6.1.1 gives the minimum, maximum and typical values of the capacitance and the parasitic.

#### 7.6.6.1.1 1.2V Digital LDO

Ball name: VDD

Table 7-5. 1.2V Dig LDO Output

|  | Min | Тур | Max | Unit |
|--|-----|-----|-----|------|
| Recommended value(s) of C                  | 3.6 | 4.7 | 5.2 | uF   |
| Allowed output parasitic inductance Lp (1) | 1   | 1.5 | 2   | nH   |
| Allowed output parasitic resistance Rp (2) | 15  | 20  | 35  | mOhm |

- (1) Lp = LT1 + ESL1 + LT2
- (2) Rp = RT1 + ESR1 + RT2

#### 7.6.6.2 Two-capacitor rail

1.2V RF LDO, 1.2V SRAM LDO and 1.0V RF LDO require two decoupling capacitors with typical values of 10uF and 2.2uF.

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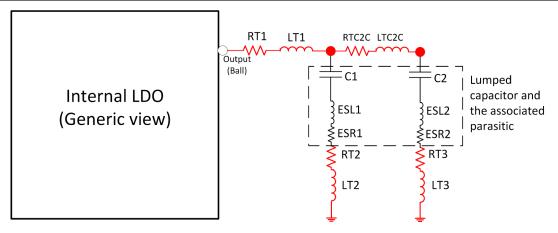


Figure 7-5. Parasitic offered by different portion of the output path for two capacitors

The parasitic offered by different portion of the output path is illustrated in Figure 7-5. As shown in figure, the output path can be divided into four portions:

**Ball to first capacitor:** "RT1" and "LT1" are the parasitic resistance and inductance offered by the ball to the first capacitor lead.

**Along the first capacitor:** "ESL1" and "ESR1" are the effective series inductance and resistance of the first decoupling capacitor. "RT2" and "LT2" are the ground trace resistance and inductance respectively of the first capacitor ground trace.

**First capacitor lead to second capacitor lead:** "RTC2C" and "LTC2C" are the resistance and inductance of the trace between two capacitors.

**Along the second capacitor:** "ESL2" and "ESR2" are the effective series inductance and resistance of the second decoupling capacitor. "RT3" and "LT3" are the ground trace resistance and inductance respectively of the second capacitor ground trace.

#### Note

Both the capacitors are recommended to be placed close to the respective ball.

#### 7.6.6.2.1 1.2V RF LDO

Ball name: VDDA\_12RF

Table 7-6. 1.2V RF LDO Output

|                      | 145.6 . 6. 1.21 .                                |     |      |      |      |
|----------------------|--|-----|------|------|------|
|                      |  | Min | Тур  | Max  | Unit |
| Recommended          | C1   | 4.9 | 10.0 | 11.0 | uF   |
| value(s) of C        | C2   | 1.3 | 2.2  | 2.4  | uF   |
| Allowed output       | Ball to 1st Capacitor lead (LT1)                 | 0.3 |      | 0.6  | nH   |
| parasitic inductance | Along 1 <sup>st</sup> Capacitor (ESL1 + LT2)     | 0.4 |      | 0.7  |      |
|                      | Between two Capacitor leads (LTC2C)              | 0.1 |      | 0.3  |      |
|                      | Along the 2 <sup>nd</sup> Capacitor (ESL2 + LT3) | 0.4 |      | 0.7  |      |
| Allowed output       | Ball to 1 <sup>st</sup> Capacitor lead (RT1)     | 1   |      | 5    | mOhm |
| parasitic resistance | Along 1 <sup>st</sup> Capacitor (ESR1 + RT2)     | 15  |      | 25   |      |
|                      | Between two Capacitor leads (RTC2C)              | 1   |      | 5    |      |
|                      | Along the 2 <sup>nd</sup> Capacitor (ESR2 + RT3) | 15  |      | 25   |      |

#### 7.6.6.2.2 1.2V SRAM LDO

Ball name: VDD\_SRAM

Table 7-7. 1.2V SRAM LDO Output

|                          |  | Min | Тур  | Max  | Unit |
|--------------------------|--|-----|------|------|------|
| Recommended value(s)     | C1   | 4.9 | 10.0 | 11.0 | uF   |
| of C                     | C2   | 1.3 | 2.2  | 2.4  | uF   |
| Allowed output parasitic | Ball to 1 <sup>st</sup> Capacitor lead (LT1)     | 0.5 |      | 1.0  | nH   |
| inductance               | Along 1 <sup>st</sup> Capacitor (ESL1 + LT2)     | 1.0 |      | 1.5  |      |
|                          | Between two Capacitor leads (LTC2C)              | 0.5 |      | 1.0  |      |
|                          | Along the 2 <sup>nd</sup> Capacitor (ESL2 + LT3) | 1.0 |      | 1.5  |      |
| Allowed output parasitic | Ball to 1 <sup>st</sup> Capacitor lead (RT1)     |     |      | 1    | mOhm |
| resistance               | Along 1 <sup>st</sup> Capacitor (ESR1 + RT2)     | 15  |      | 35   |      |
|                          | Between two Capacitor leads (RTC2C)              |     |      | 1    |      |
|                          | Along the 2 <sup>nd</sup> Capacitor (ESR2 + RT3) | 15  |      | 35   |      |

#### 7.6.6.2.3 1.0V RF LDO

Ball name: VDDA 10RF

Table 7-8, 1.0V RF LDO Output

|                          | 14516 7 0: 1:0 4 13                              |     |      |      |      |
|--------------------------|--|-----|------|------|------|
|                          |  | Min | Тур  | Max  | Unit |
| Recommended value(s)     | C1   | 4.9 | 10.0 | 11.0 | uF   |
| of C                     | C2   | 1.3 | 2.2  | 2.4  | uF   |
| Allowed output parasitic | Ball to 1st Capacitor lead (LT1)                 | 0.3 | 0.3  | 0.6  | nH   |
| inductance               | Along 1 <sup>st</sup> Capacitor (ESL1 + LT2)     | 0.3 |      | 1.0  |      |
|                          | Between two Capacitor leads (LTC2C)              | 0.1 |      | 0.3  |      |
|                          | Along the 2 <sup>nd</sup> Capacitor (ESL2 + LT3) | 0.3 |      | 1.0  |      |
| Allowed output parasitic | Ball to 1st Capacitor lead (RT1)                 | 1   |      | 5    | mOhm |
| resistance               | Along 1 <sup>st</sup> Capacitor (ESR1 + RT2)     | 15  |      | 25   |      |
|                          | Between two Capacitor leads (RTC2C)              | 1   |      | 5    |      |
|                          | Along the 2 <sup>nd</sup> Capacitor (ESR2 + RT3) | 15  |      | 25   |      |

#### 7.6.7 Noise and Ripple Specifications

The 1.8V power supply ripple specifications mentioned in Table 7-9 are defined to meet a target spur level of -105 dBc (RF Pin = -15 dBm) at the RX. The spur and ripple levels have a dB-to-dB relationship, for example, a 1-dB increase in supply ripple leads to a ~1 dB increase in spur level. Values quoted are peak-peak levels for a sinusoidal input applied at the specified frequency. These values are being optimized and are subject to change.

Table 7-9. Noise and Ripple Specifications

| Table : Trible and Tappie eperinations |                     |                |                      |              |  |
|--|---------------------|----------------|----------------------|--------------|--|
| EDEO (I-UZ)                            | NOISE SPECIFICATION |                | RIPPLE SPECIFICATION |              |  |
| FREQ (kHZ)                             | 1.8 V (μV/√Hz)      | 1.2V (μV/√Hz)1 | 1.8 V (mVpp)         | 1.2V (mVpp)1 |  |
| 10                                     | 6.057               | 44.987         | 0.035                | 1.996        |  |
| 100                                    | 2.677               | 26.801         | 0.760                | 2.233        |  |
| 200                                    | 2.388               | 28.393         | 0.955                | 3.116        |  |
| 500                                    | 0.757               | 9.559          | 0.504                | 1.152        |  |
| 1000                                   | 0.419               | 1.182          | 0.379                | 0.532        |  |
| 2000                                   | 0.179               | 1.256          | 0.153                | 0.561        |  |
|  |                     |                |                      |              |  |

Table 7-9. Noise and Ripple Specifications (continued)

| FREQ (kHZ) | NOISE SPECIFIC |                | RIPPLE SPE   | CIFICATION   |
|------------|----------------|----------------|--------------|--------------|
| FREQ (KHZ) | 1.8 V (μV/√Hz) | 1.2V (μV/√Hz)1 | 1.8 V (mVpp) | 1.2V (mVpp)1 |
| 5000       | 0.0798         | 0.667          | 0.079        | 0.297        |
| 10000      | 0.0178         | 0.104          | 0.017        | 0.046        |

1. 1.2V noise/ripple specification is only for power optimized supply configurations. For BOM optimized topology 1.2V noise/ripple specification is not applicable.

#### Note

Same 1.8V noise/ripple specification is applicable for the 1.8V supply in the BOM optimized topology

### 7.7 Power Save Modes

Table 7-10 lists the supported power states.

**Table 7-10. Device Power States** 

| Power State | Details   |
|-------------|---|
| Active      | Active Power State is when RF/chirping activity is ongoing  |
| Processing  | Processing Power State is when data is being processed RF turned off <sup>(1)</sup>   |
| Idle        | Idle Power State is during inter-frame/inter-burst/inter-chirp idle time  |
| Deep Sleep  | Lowest possible power state of the device where the contents of the device can be retained (Application Image, Chirp Profile etc) and device need not boot from scratch again.  Device can enter this state after the frame processing is complete in order to save power significantly.  Deep sleep exit can be through a number of external wakeup sources and internal timing maintenance. |

(1) The power consumed here also includes the Hardware Accelerator Power Consumption.

#### 7.7.1 Typical Power Consumption Numbers

Table 7-11 and Table 7-12 lists the typical power consumption for each power save modes in different power topologies and antenna configurations for a nominal device at 25C ambient temperature and nominal voltage conditions.

Table 7-13 and Table 7-14 lists the typical power consumption for two different use-cases.

Table 7-11. Estimated Power Consumed in 3.3V IO Mode

| Power Mode        |  | Power Consumption (mW) |                    |  |
|-------------------|--|------------------------|--------------------|--|
|                   |  | Power Optimized Mode   | BOM Optimized Mode |  |
| Active (2TX, 3RX) | Sampling: 12.5 Msps                                      | 1326                   | 1802               |  |
| Active (2TX, 2RX) | Start Freq = 77GHz                                       | 1185                   | 1607               |  |
| Active (1TX, 2RX) | BW = 2GHz  | 936                    | 1235               |  |
| Active (1TX, 1RX) | TX Back off = 0dB<br>RX gain = 30dB                      | 884                    | 1163               |  |
| Processing        | Major motion SDK OOB chain is used for measurement       | 78                     | 112                |  |
| Idle (Frame Idle) | APPSS CM4 = 20MHz, FECSS,<br>HWA powered off, SPI active | 11.3                   | 19.2               |  |
| Deep sleep        | Memory Retained = 114KB                                  | 0.66                   | 0.67               |  |

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Table 7-12. Estimated Power Consumed in 1.8V IO Mode

| Power Mode        |  | Power Consumption (mW) |                    |  |
|-------------------|--|------------------------|--------------------|--|
|                   |  | Power Optimized Mode   | BOM Optimized Mode |  |
| Active (2TX, 3RX) | Sampling: 12.5 Msps                                      | 1326                   | 1802               |  |
| Active (2TX, 2RX) | Start Freq = 77GHz                                       | 1185                   | 1607               |  |
| Active (1TX, 2RX) | BW = 2GHz  | 936                    | 1235               |  |
| Active (1TX, 1RX) | TX Back off = 0dB<br>RX gain = 30dB                      | 884                    | 1163               |  |
| Processing        | Major motion SDK OOB chain is used for measurement       | 78                     | 112                |  |
| Idle (Frame Idle) | APPSS CM4 = 20MHz, FECSS,<br>HWA powered off, SPI active | 11                     | 19                 |  |
| Deep sleep        | Memory Retained = 114KB                                  | 0.48                   | 0.48               |  |

Table 7-13. Use-Case Power Consumed in 3.3V Power Optimized Topology (Level Sensing Application)

| Parameter                                      |  | Condition       | Typical power (mW) |
|--|--|-----------------|--------------------|
| Average Power Consumption (Presence Detection) | RF Front End Configuration: 1TX, 1RX  12.5Msps Sampling Rate Ramp End time = 45us Chirp Idle Time = 6us Chirp Slope = 75MHz/us Number of chirps per burst = 2 Burst Periodicity = 220us Number of bursts per frame = 1 Device configured to go to deep sleep state after active operation. Memory Retained in deep sleep = 114KB | 1Hz Update Rate | 1.02               |

Table 7-14. Use-Case Power Consumed in 3.3V Power Optimized Topology (Kick to Open Application)

| Parameter                                      |  | Condition       | Typical power (mW) |
|--|--|-----------------|--------------------|
| Average Power Consumption (Presence Detection) | RF Front End Configuration: 1TX, 1RX 4.76Msps Sampling Rate Ramp End time = 34us Chirp Idle Time = 8us Chirp Slope = 102.98MHz/us Number of chirps per burst = 1 Burst Periodicity = 1500us Number of bursts per frame = 2 Device configured to go to deep sleep state after active operation. Memory Retained in deep sleep = 114KB | 2Hz Update Rate | 2.06               |

## 7.8 Peak Current Requirement per Voltage Rail

Table 7-15 provides the max split rail current numbers.

Table 7-15. Maximum Peak Current per Voltage Rail

|                     | I                         |  |  |  |
|---------------------|---------------------------|--|--|--|
| Mode <sup>(1)</sup> | IO Voltage <sup>(3)</sup> | Maximum Current (mA) <sup>(2)</sup>                              |  |  |
|                     |                           | 1.2V: total current drawn<br>by all nodes driven by<br>1.2V rail | 1.8V: total current drawn<br>by all nodes driven by<br>1.8V rail | 3.3V: total current drawn<br>by all nodes driven by<br>3.3V rail |
| BOM Optimized       | 3.3V                      | NA   | 1425   | 90   |
| BOM Optimized       | 1.8V                      | NA   | 1450   | NA   |
| Power Optimized     | 3.3V                      | 1100   | 270  | 90   |

### Table 7-15. Maximum Peak Current per Voltage Rail (continued)

| Mode <sup>(1)</sup> | IO Voltage <sup>(3)</sup> | Maximum Current (mA) <sup>(2)</sup> |     |    |
|---------------------|---------------------------|-------------------------------------|-----|----|
| Power Optimized     | 1.8V                      | 1100                                | 295 | NA |

- (1) Exercise full functionality of device, including 2TX, 3RX simultaneous operation, HWA, M4F and various host comm/interface peripherals active (CAN, LIN, I2C, GPADC), test across full temperature range
- 2) The specified current values are at typical supply voltage level.
- (3) The exact VIOIN current depends on the peripherals used and the frequency of operation.

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### 7.9 RF Specification

Over recommended operating conditions (unless otherwise noted)

|                            | PARAMETER   |              | MIN | TYP  | MAX  | UNIT   |
|----------------------------|---|--------------|-----|------|------|--------|
|                            | Noise figure  | 76 to 81 GHz |     | 14   |      | dB     |
|                            | 1-dB compression point (Out Of Band) <sup>(2)</sup> |              |     | -10  |      | dBm    |
|                            | Maximum gain  |              |     | 40   |      | dB     |
|                            | Gain range  |              | 10  |      | dB   |        |
| Receiver <sup>(1)</sup>    | Gain step size                                      |              | 2   |      | dB   |        |
|                            | IF bandwidth <sup>(3)</sup>                         |              |     | 5    | MHz  |        |
|                            | ADC sampling rate (real)                            |              |     | 12.5 | Msps |        |
|                            | ADC resolution                                      |              |     | 12   |      | Bits   |
|                            | S11   |              |     | -10  |      | dB     |
| Transmitter <sup>(1)</sup> | Output Power  |              |     | 11   |      | dBm    |
| Transmitter                | S11   |              | -10 |      | dB   |        |
|                            | Frequency range                                     | 76           |     | 81   | GHz  |        |
| Clock<br>subsystem         | Ramp rate   |              |     |      | 400  | MHz/µs |
|                            | Phase noise at 1-MHz offset                         | 76 to 81 GHz |     | -89  |      | dBc/Hz |

- (1) The polarity of LO signal for TX2 is inverted with respect to TX1, hence the phase of the signal is expected to have 180<sup>0</sup> offset. Enabling BPM on a transmitter chain will create additional 180<sup>0</sup> phase offset on that chain. The polarity of LO signal for RX2 is inverted with respect to RX1 and RX3, hence the phase of the signal is expected to have 180<sup>0</sup> offset. This can be taken care during post-processing, in HWA or external processing.
- (2) 1-dB Compression Point (Out Of Band) is measured by feed a Continuous wave Tone well below the HPF cut-off frequency.
- (3) The analog IF stages include high-pass filtering, with configurable first-order high-pass corner frequency. The set of available HPF corners is summarized as follows:

| Available HPF Corner Freque | cies (kHz) |
|-----------------------------|------------|
| 175, 350, 700, 1400         |            |

The filtering performed by the digital baseband chain is targeted to provide less than ±0.5 dB pass-band ripple/droop.

Figure 7-6 shows variations of noise figure and in-band P1dB parameters with respect to receiver gain programmed.

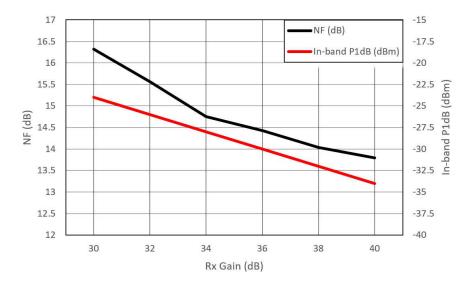


Figure 7-6. Noise Figure, In-band P1dB vs Receiver Gain



#### 7.10 Supported Front End features

- TX output
  - Binary Phase Modulation supported on each TX
- RX gain
  - Real RX channels
  - Total RX gain range of 30dB to 40dB, in 2dB steps
- VCO
  - Single VCO covering entire RF sweep bandwidth up to 5GHz.
- · High-pass filter
  - Supports corner frequency options 175KHz, 350KHz, 700KHz, 1400KHz
  - First-order high pass filter only
- Low-pass filter
  - Max IF bandwidth supported is 5MHz
  - 40dB stopband rejection, two filtering options supported
  - 80% visibility IF bandwidth is 80% of Nyquist and is 30% faster due to quicker settling time, compared with 90% visibility
  - 90% visibility IF bandwidth is 90% of Nyquist (has longer setting time due to larger filter length)
- Supported ADC sampling rates
  - 1.0, 1.25, 1.667, 2.0, 2.5, 4.0, 5.0, 6.667, 7.692, 10.0, 12.5Msps
- · Timing Engine
  - Support for chirps, bursts and frames
    - Longer frame idle time gives more power saving than a longer burst idle time. Further, a longer chirp
      idle time gives lesser power saving than a longer burst idle time. For more details please refer power
      calculator in the mmWave sensing estimator.
    - · Chirp accumulation (averaging) possible across closely spaced chirps to reduce memory requirement
  - Provision for per-chirp dithering of parameters

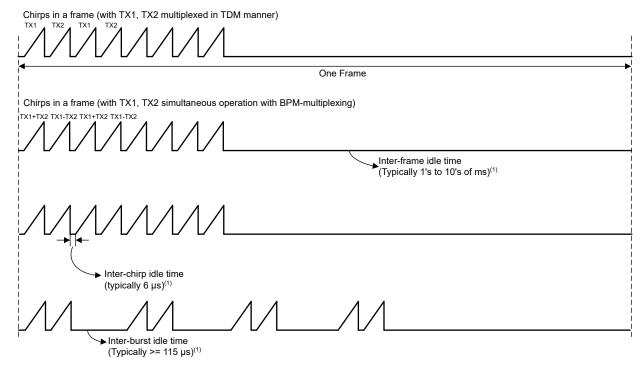


Figure 7-7. Chip Profile Supported by Timing Engine

Refer to ICD (Interface control Document).



#### 7.11 CPU Specifications

Over recommended operating conditions (unless otherwise noted)

|  | PARAMETER                                   | TYP | UNIT |
|--|---|-----|------|
| Application<br>Subsystem (M4F<br>Family) | Clock Speed                                 | 160 | MHz  |
|  | Tightly Coupled Memory - A (Program + Data) | 512 | KB   |
| Shared Memory                            | Shared L3 Memory <sup>(1)</sup>             | 256 | KB   |
|  | L3 Memory dedicated for HWA                 | 256 | KB   |

(1) L3 memory is configurable

#### 7.12 Thermal Resistance Characteristics

Table 7-16. Thermal Resistance Characteristics for FCCSP Package [AMF0102A]

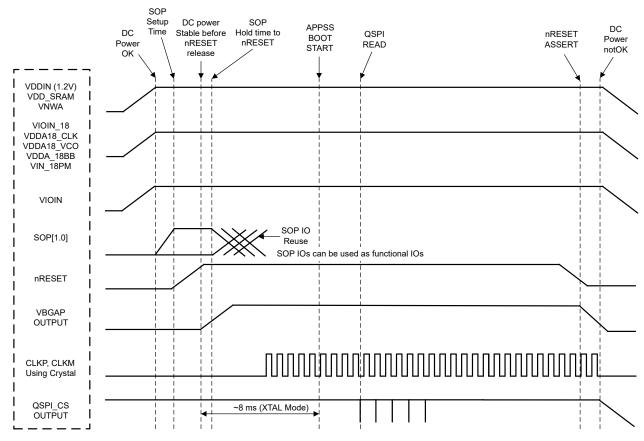
| THERMAL METRICS <sup>(1)</sup> (4) |                         | °C/W <sup>(2)</sup> (3) |
|------------------------------------|-------------------------|-------------------------|
| RΘ <sub>JC</sub>                   | Junction-to-case        | 8.5                     |
| RΘ <sub>JB</sub>                   | Junction-to-board       | 6.2                     |
| RΘ <sub>JA</sub>                   | Junction-to-free air    | 24.7                    |
| Psi <sub>JC</sub>                  | Junction-to-package top | 0.36                    |
| Psi <sub>JB</sub>                  | Junction-to-board       | 6.2                     |

- (1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.
- °C/W = degrees Celsius per watt.
- (3) These values are based on a JEDEC-defined 2S2P system (with the exception of the Theta JC [RO<sub>JC</sub>] value, which is based on a JEDEC-defined 1S0P system) and will change based on environment as well as application. For more information, see these EIA/JEDEC standards:
  - · JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions Natural Convection (Still Air)
  - JESD51-3, Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages
  - JESD51-7, High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages
  - JESD51-9, Test Boards for Area Array Surface Mount Package Thermal Measurements
- (4) Test Condition: Power=1.305W at 25°C

#### 7.13 Timing and Switching Characteristics

#### 7.13.1 Power Supply Sequencing and Reset Timing

The AWRL1432 device expects all external voltage rails to be stable before reset is deasserted. Figure 7-8 describes the device wake-up sequence.



A. MCU\_CLK\_OUT in autonomous mode, where AWRL1432 application is booted from the serial flash, MCU\_CLK\_OUT is not enabled by default by the device bootloader.

Figure 7-8. Device Wake-up Sequence

#### 7.13.2 Synchronized Frame Triggering

The AWRL1432 device supports a hardware based mechanism to trigger radar frames. An external host can pulse the SYNC\_IN signal to start radar frames. The typical time difference between the rising edge of the external pulse and the frame transmission on air (Tlag) is about 160 ns. There is also an additional programmable delay that the user can set to control the frame start time.

The periodicity of the external SYNC\_IN pulse should be always greater than the active frame duration in all instances.



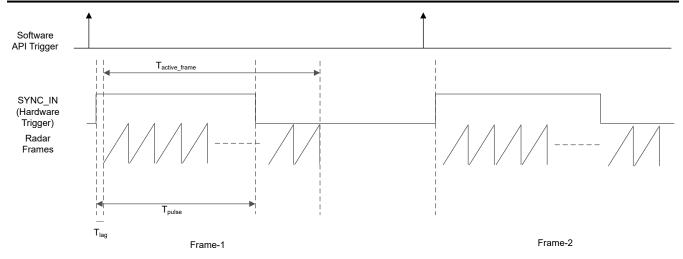


Figure 7-9. Sync In Hardware Trigger

**Table 7-17. Frame Trigger Timing** 

| PARAMETER                 | DESCRIPTION           | MIN          | MAX                         | UNIT |
|---------------------------|-----------------------|--------------|-----------------------------|------|
| T <sub>active_frame</sub> | Active frame duration | User defined |                             | ne   |
| T <sub>pulse</sub>        |                       | 25           | < T <sub>active_frame</sub> | ns   |

#### 7.13.3 Input Clocks and Oscillators

#### 7.13.3.1 Clock Specifications

The AWRL1432 requires external clock source (that is, a 40-MHz crystal or external oscillator to CLKP) for initial boot and as a reference for an internal APLL hosted in the device. An external crystal connected to the device pins Figure 7-10 shows the crystal implementation.

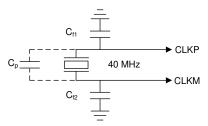


Figure 7-10. Crystal Implementation

#### Note

The load capacitors,  $C_{f1}$  and  $C_{f2}$  in Figure 7-10, should be chosen such that Equation 1 is satisfied.  $C_L$  in the equation is the load specified by the crystal manufacturer. All discrete components used to implement the oscillator circuit should be placed as close as possible to the associated oscillator CLKP and CLKM pins.

$$C_{L} = C_{f1} \times \frac{C_{f2}}{C_{f1} + C_{f2}} + C_{P}$$
 (1)

Table 7-18 lists the electrical characteristics of the clock crystal.

Table 7-18. Crystal Electrical Characteristics (Oscillator Mode)

| NAME           | DESCRIPTION                          | MIN | TYP | MAX | UNIT |
|----------------|--------------------------------------|-----|-----|-----|------|
| f <sub>P</sub> | Parallel resonance crystal frequency |     | 40  |     | MHz  |

Table 7-18. Crystal Electrical Characteristics (Oscillator Mode) (continued)

|                     | rable 7 10. Orystal Electrical Characteristics (Oscillato | i ilioac, | ,001111110 | icaj |      |
|---------------------|---|-----------|------------|------|------|
| NAME                | DESCRIPTION   | MIN       | TYP        | MAX  | UNIT |
| C <sub>L</sub>      | Crystal load capacitance                                  | 5         | 8          | 12   | pF   |
| ESR                 | Crystal ESR   |           |            | 50   | Ω    |
| Temperature range   | Expected temperature range of operation                   | -40       |            | 125  | °C   |
| Frequency tolerance | Crystal frequency tolerance <sup>(1)</sup> (2) (3)        | -200      |            | 200  | ppm  |
| Drive level         |   |           | 50         | 200  | μW   |

- (1) The crystal manufacturer's specification must satisfy this requirement.
- (2) Includes initial tolerance of the crystal, drift over temperature, aging and frequency pulling due to incorrect load capacitance.
- (3) Crystal tolerance affects radar sensor accuracy.

In the case where an external clock is used as the clock resource, the signal is fed to the CLKP pin only; CLKM is grounded. The phase noise requirement is very important when a 40-MHz clock is fed externally. Table 7-19 lists the electrical characteristics of the external clock signal.

Table 7-19. External Clock Mode Specifications

| _                                    | able 1-13. External Glock |      | PECIFICATIO | N    |         |
|--------------------------------------|---------------------------|------|-------------|------|---------|
| PARAM                                | ETER                      | MIN  | TYP         | MAX  | UNIT    |
|                                      | Frequency                 |      | 40          |      | MHz     |
|                                      | AC-Amplitude              | 700  |             | 1200 | mV (pp) |
|                                      | DC-V <sub>il</sub>        | 0.00 |             | 0.20 | V       |
| Input Clock:                         | DC-V <sub>ih</sub>        | 1.6  |             | 1.95 | V       |
| External AC-coupled sine wave or DC- | Phase Noise at 1 kHz      |      |             | -132 | dBc/Hz  |
| coupled square wave Phase Noise      | Phase Noise at 10 kHz     |      |             | -143 | dBc/Hz  |
| referred to 40 MHz                   | Phase Noise at 100 kHz    |      |             | -152 | dBc/Hz  |
|                                      | Phase Noise at 1 MHz      |      |             | -153 | dBc/Hz  |
|                                      | Duty Cycle                | 35   |             | 65   | %       |
|                                      | Frequency Tolerance       | -100 |             | 100  | ppm     |

#### 7.13.4 MultiChannel buffered / Standard Serial Peripheral Interface (McSPI)

The McSPI module is a multichannel transmit/receive, controller/peripheral synchronous serial bus

#### 7.13.4.1 McSPI Features

The McSPI modules include the following main features:

- Serial clock with programmable frequency, polarity, and phase for each channel
- Wide selection of SPI word lengths, ranging from 4 to 32 bits
- Up to four channels in controller mode, or single channel in receive mode
- Controller multichannel mode:
  - Full duplex/half duplex
  - Transmit-only/receive-only/transmit-and-receive modes
  - Flexible input/output (I/O) port controls per channel
  - Programmable clock granularity
  - Per channel configuration for clock definition, polarity enabling, and word width
- Single interrupt line for multiple interrupt source events
- Enable the addition of a programmable start-bit for McSPI transfer per channel (start-bit mode)
- Supports start-bit write command
- · Supports start-bit pause and break sequence
- Programmable shift operations (1-32 bits)
- Programmable timing control between chip select and external clock generation
- Built-in FIFO available for a single channel

#### 7.13.4.2 SPI Timing Conditions

Table 7-20 presents timing conditions for McSPI

#### Table 7-20. McSPI Timing Conditions

|                   |                         | MIN | TYP MAX | UNIT |  |
|-------------------|-------------------------|-----|---------|------|--|
| Input Condit      | ions                    |     |         |      |  |
| t <sub>R</sub>    | Input rise time         | 1   | 3       | ns   |  |
| t <sub>F</sub>    | Input fall time         | 1   | 3       | ns   |  |
| Output Cond       | Output Conditions       |     |         |      |  |
| C <sub>LOAD</sub> | Output load capacitance | 2   | 15      | pF   |  |

#### 7.13.4.3 SPI—Controller Mode

#### 7.13.4.3.1 Timing and Switching Requirements for SPI - Controller Mode

Table 7-21 and Table 7-21 present timing requirements for SPI - Controller Mode.

#### Table 7-21. SPI Timing Requirements - Controller Mode

| NO. <sup>(1)</sup> (8) |                              |   | MODE | MIN MAX | UNIT |
|------------------------|------------------------------|---|------|---------|------|
| SM4                    | t <sub>su(MISO-SPICLK)</sub> | Setup time, SPI_D[x] valid before SPI_CLK active edge (1) |      | 5       | ns   |
| SM5                    | t <sub>h(SPICLK-MISO)</sub>  | Hold time, SPI_D[x] valid after SPI_CLK active edge (1)   |      | 3       | ns   |

### Table 7-22. SPI Switching Characteristics - Controller Mode

| NO. <sup>(1)</sup> |                          |  | MODE | MIN MAX                            | UNIT |
|--------------------|--------------------------|--|------|------------------------------------|------|
| SM1                | t <sub>c(SPICLK)</sub>   | Cycle time, SPI_CLK (1) (2)              |      | 24.6 <sup>(3)</sup>                | ns   |
| SM2                | t <sub>w</sub> (SPICLKL) | Typical Pulse duration, SPI_CLK low (1)  |      | -1 +<br>0.5P <sup>(3)</sup><br>(4) | ns   |
| SM3                | t <sub>w(SPICLKH)</sub>  | Typical Pulse duration, SPI_CLK high (1) |      | -1 +<br>0.5P <sup>(4)</sup>        | ns   |

Table 7-22. SPI Switching Characteristics - Controller Mode (continued)

| NO. <sup>(1)</sup> (8) |                              |  | MODE  | MIN                   | MAX | UNIT |
|------------------------|------------------------------|--|---|-----------------------|-----|------|
| SM6                    | t <sub>d</sub> (SPICLK-SIMO) | Delay time, SPI_CLK active edge to SPI_D[x] transition (1) |   | -2                    | 5   | ns   |
| SM7                    | t <sub>sk(CS-SIMO)</sub>     | Delay time, SPI_CS[x] active to SPI_D[x] transition        |   | 5                     |     | ns   |
| SM8                    | t <sub>d</sub> (spiclk-cs)   | Delay time, SPI_CS[x] active to SPI_CLK first edge         | Controller_PHA0_POL<br>0;<br>Controller_PHA0_POL<br>1; <sup>(5)</sup> | -4 + B <sup>(6)</sup> |     | ns   |
|                        |                              |  | Controller_PHA1_POL<br>0;<br>Controller_PHA1_POL<br>1; <sup>(5)</sup> | -4 + A <sup>(7)</sup> |     | ns   |
| SM9                    | t <sub>d</sub> (spiclk-cs)   | Delay time, SPI_CLK last edge to SPI_CS[x] inactive        | Controller_PHA0_POL<br>0;<br>Controller_PHA0_POL<br>1; <sup>(5)</sup> | -4 + A <sup>(7)</sup> |     | ns   |
|                        |                              |  | Controller_PHA1_POL<br>0;<br>Controller_PHA1_POL<br>1; (5)            | -4 + B <sup>(6)</sup> |     | ns   |
| SM11                   | Cb                           | Capacitive load for each bus line                          |   | 3                     | 15  | pF   |

- (1) P = This timing applies to all configurations regardless of SPI\_CLK polarity and which clock edges are being used to drive output data and capture input data
- (2) Related to the SPI\_CLK maximum frequency
- (3) 20 ns cycle time = 50 MHz
- (4) P = SPICLK period
- (5) SPI\_CLK phase is programmable with the PHA bit of the SPI\_CH(i)CONF register
- (6) B = (TCS + .5) × TSPICLKREF, where TCS is a bit field of the SPI\_CH(i)CONF register and Fratio = Even >= 2.
- (7) When P = 20.8 ns, A = (TCS + 1) × TSPICLKREF, where TCS is a bit field of the SPI\_CH(i)CONF register.

  When P > 20.8 ns, A = (TCS + 0.5) × Fratio × TSPICLKREF, where TCS is a bit field of the SPI\_CH(i)CONF register.
- (8) The IO timings provided in this section are applicable for all combinations of signals for SPI1 and SPI2. However, the timings are only valid for SPI3 and SPI4 if signals within a single IOSET are used. The IOSETs are defined in the following tables.

This timing applies to all configurations regardless of SPI\_CLK polarity and which clock edges are being used to drive output data and capture input data

### Note

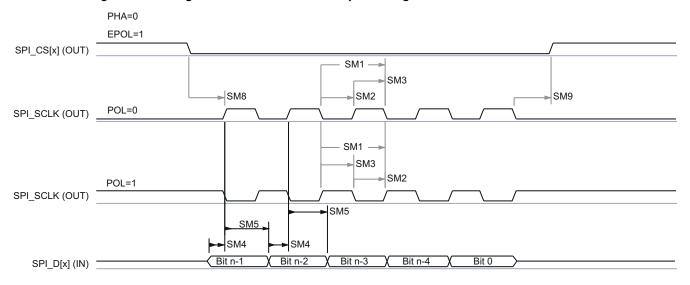
Supported frequency of Radar SPI Peripheral mode is 40MHz in full cycle and 20MHz in Half cycle mode.

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## 7.13.4.3.2 Timing and Switching Characteristics for SPI Output Timings—Controller Mode



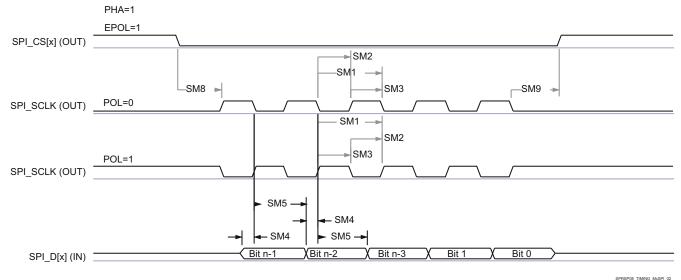
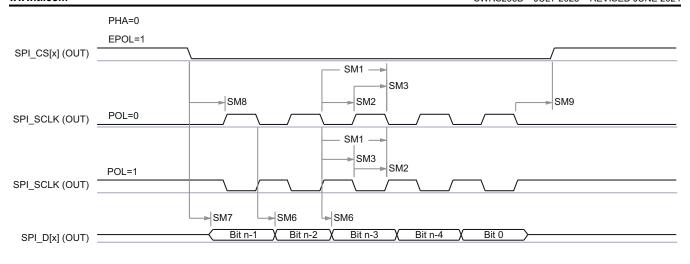


Figure 7-11. SPI Timing -Controller Mode Receive

SPRSP08\_TIMING\_McSPI\_02



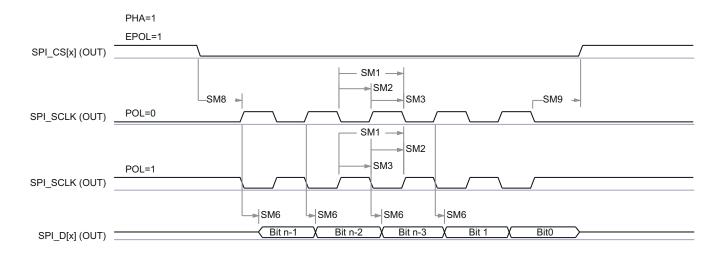


Figure 7-12. SPI Timing- Controller Mode Transmit

### 7.13.4.4 SPI—Peripheral Mode

## 7.13.4.4.1 Timing and Switching Requirements for SPI - Peripheral Mode

Table 7-23 and Table 7-24 present timing requirements for SPI -Peripheral Mode.

Table 7-23. SPI Timing Requirements - Peripheral Mode

| NO. <sup>(1) (3)</sup> | PARAMETER                    | DESCRIPTION   | MIN                   | MAX | UNIT |
|------------------------|------------------------------|---|-----------------------|-----|------|
| SS1                    | t <sub>c(SPICLK)</sub>       | Cycle time, SPI_CLK                                   | 24.6                  |     | ns   |
| SS2                    | t <sub>w(SPICLKL)</sub>      | Typical Pulse duration, SPI_CLK low                   | 0.45*P <sup>(2)</sup> |     | ns   |
| SS3                    | t <sub>w(SPICLKH)</sub>      | Typical Pulse duration, SPI_CLK high                  | 0.45*P <sup>(2)</sup> |     | ns   |
| SS4                    | t <sub>su(SIMO-SPICLK)</sub> | Setup time, SPI_D[x] valid before SPI_CLK active edge | 3                     |     | ns   |
| SS5                    | t <sub>h(SPICLK-SIMO)</sub>  | Hold time, SPI_D[x] valid after SPI_CLK active edge   | 1                     |     | ns   |
| SS8                    | t <sub>su(CS-SPICLK)</sub>   | Setup time, SPI_CS[x] valid before SPI_CLK first edge | 5                     |     | ns   |
| SS9                    | t <sub>h(SPICLK-CS)</sub>    | Hold time, SPI_CS[x] valid after SPI_CLK last edge    | 5                     |     | ns   |
| SS10                   | sr                           | Input Slew Rate for all pins                          | 1                     | 3   | ns   |
| SS11                   | Cb                           | Capacitive load on D0 and D1                          | 2                     | 15  | pF   |

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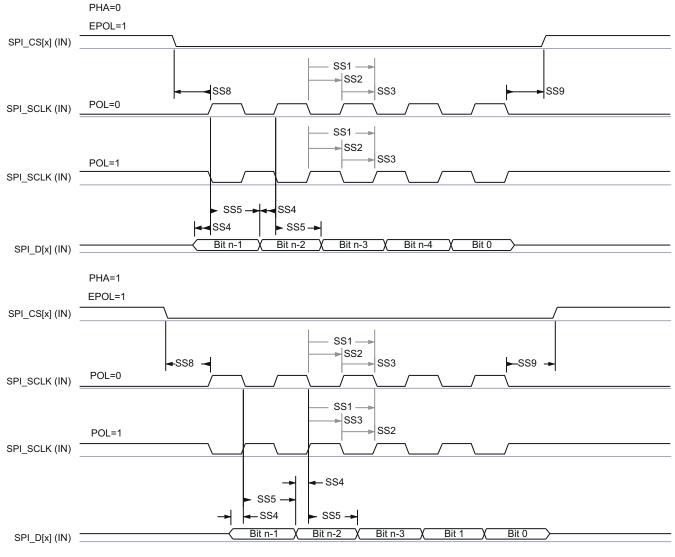


Table 7-24. SPI Switching Characteristics Peripheral Mode

| NO. | PARAMETER                   | DESCRIPTION  | MIN  | MAX  | UNIT |
|-----|-----------------------------|--|------|------|------|
| SS6 | t <sub>d(SPICLK-SOMI)</sub> | Delay time, SPI_CLK active edge to McSPI_somi transition   | 0    | 5.77 | ns   |
| SS7 | t <sub>sk(CS-SOMI)</sub>    | Delay time, SPI_CS[x] active edge to McSPI_somi transition | 5.77 |      | ns   |

- (1) P = This timing applies to all configurations regardless of SPI\_CLK polarity and which clock edges are used to drive output data and capture input data.
- (2) P = SPICLK period.
- (3) PHA = 0; SPI CLK phase is programmable with the PHA bit of the SPI CH(i)CONF register.

### 7.13.4.4.2 Timing and Switching Characteristics for SPI Output Timings—Secondary Mode



SPRSP08\_TIMING\_McSPI\_04

Figure 7-13. SPI Timing - Peripheral mode Receive

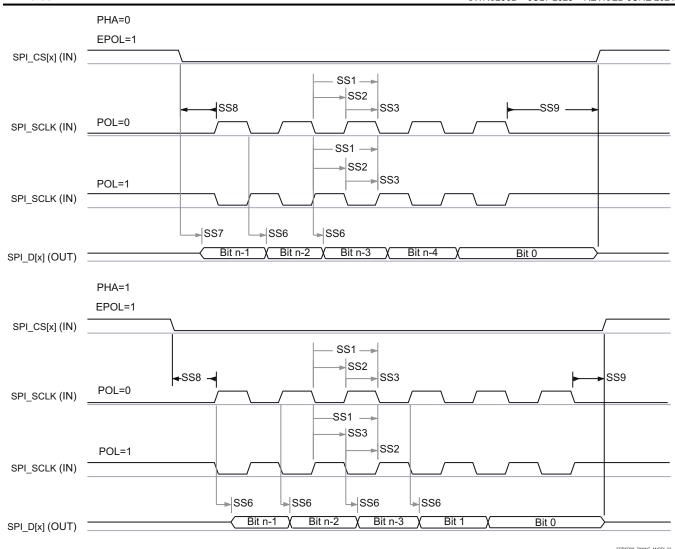


Figure 7-14. SPI Timing - Peripheral mode Transmit

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## 7.13.5 RDIF Interface Configuration

The supported Radar Data InterFace (RDIF) is developed as a debug interface (for example: to capture raw ADC data) and not as a production interface. The RDIF has four data lanes, one Bit Clock lane, and one Frame Clock lane. From this interface, high-speed data is sent out for debug purposes. The RDIF interface supports the following data rates<sup>1</sup>:

- 400Mbps
- 320Mbps
- 200Mbps
- 160Mbps

### 7.13.5.1 RDIF Interface Timings

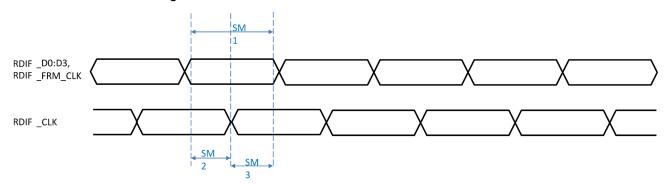


Figure 7-15. RDIF Timing Requirements

Table 7-25. Timing Requirements for RDIF Interface

| Table 1 201 1 mining 1 to quinomonio 101 1 to 11 minoritate |                               |   |                |     |     |      |  |  |
|---|-------------------------------|---|----------------|-----|-----|------|--|--|
| No.   | PARAMETER                     | DESCRIPTION   | MODE           | MIN | MAX | UNIT |  |  |
| SM1   | Tb (RDIF_D[x])                | Bit Interval, RDIF_d[x]   | Internal Clock | 9.6 |     | ns   |  |  |
| SM2   | Tvb<br>(RDIF_D[x] - RDIF_CLK) | Data valid time, RDIF_d[x] and RDIF_frm_clk valid before RDIF_clk active edge | Internal Clock | 4.8 |     | ns   |  |  |
| SM3   | Tva<br>(RDIF_CLK - RDIF_D[x]) | Data valid time, RDIF_d[x] valid after RDIF_clk active edge                   | Internal Clock | 4.8 |     | ns   |  |  |
| SM4   | C <sub>b</sub>                | Capacitive load for each bus line   |                | 3   | 15  | pF   |  |  |

Product Folder Links: AWRL1432

Aggregated data rate over four data lanes.

#### 7.13.5.2 RDIF Data Format

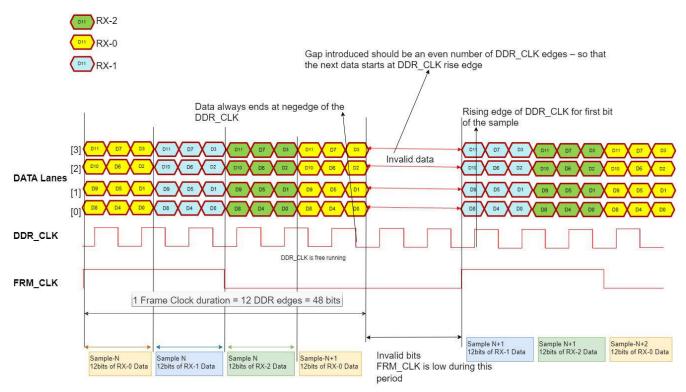


Figure 7-16. RDIF Data Format

- The samples are sent one channel by one channel as shown in the diagram above. All the 12-bits of one channel are sent on 4 data lanes in 3 DDR CLK edges, followed by next RX channel.
- The frame clock (FRM\_CLK) spans 12 DDR\_CLK edges and 48 bits are sent in 1 FRM\_CLK
- The FRM\_CLK can have gaps in between. This is required as the interface rate is greater than the incoming rate
- · DDR CLK is continuous.
- DDR\_CLK is generated from 400MHz ADC CLK (one of the ADC CLKs) selected for the DFE. It is the same 400MHz clock selected for DFE.
- New sample always starts at the rise edge of the DDR CLK
- The FRM CLK is valid for the entire data bit and is meets the Tsu/Th wrt DDR CLK.

## 7.13.6 LIN

The LIN module can be programmed to work either as an SCI or as a LIN. The SCI hardware features are augmented to achieve LIN compatibility. The LIN standard is based on the SCI (UART) serial data link format. The communication concept is single-/ multiple- with a message identification for multicast transmission between any network nodes.

The LIN has following features:

- Compatibility with LIN 1.3, 2.0, and 2.1 protocols
- Configurable Baud Rate up to 20 kpbs
- Two external pins: LIN\_RX and LIN\_TX.
- Multi-buffered receive and transmit units
- Identification masks for message filtering
- Automatic Controller header generation
  - Programmable synchronization break field
  - Synchronization field
  - Identifier field

- · Peripheral automatic synchronization
  - Synchronization break detection
  - Optional baud rate update
  - Synchronization validation
- 231 programmable transmission rates with 7 fractional bits
- Wake up on LIN\_RX dominant level from transceiver
- Automatic wake up support
  - Wakeup signal generation
  - Expiration times on wakeup signals
- · Automatic bus idle detection
- Error detection
  - Bit error
  - Bus error
  - No-response error
  - Checksum error
  - Synchronization field error
  - Parity error
- · Capability to use Direct Memory Access (DMA) for transmit and receive data.
- 2 Interrupt lines with priority encoding for:
  - Receive
  - Transmit
  - ID, error, and status
- Support for LIN 2.0 checksum
- Enhanced synchronizer finite state machine (FSM) support for frame processing
- Enhanced handling of extended frames
- Enhanced baud rate generator
- Update wakeup/go to sleep

## Table 7-26. LIN Timing Requirements

|         |                     | MIN | TYP | MAX | UNIT  |
|---------|---------------------|-----|-----|-----|-------|
| f(baud) | Supported baud rate | 1   |     | 20  | kBaud |

### 7.13.7 General-Purpose Input/Output

### 7.13.7.1 Switching Characteristics for Output Timing versus Load Capacitance (C1)

Table 7-27 lists the switching characteristics of output timing relative to load capacitance.

Table 7-27. Switching Characteristics for Output Timing versus Load Capacitance (C<sub>L</sub>)

|                | PARAMETER <sup>(1)</sup> (2) | TEST CO          | NDITIONS               | VIOIN = 1.8V | VIOIN = 3.3V | UNIT |
|----------------|------------------------------|------------------|------------------------|--------------|--------------|------|
|                |                              |                  | C <sub>L</sub> = 20 pF | 2.8          | 3.0          |      |
| t <sub>r</sub> | Max rise time                |                  | C <sub>L</sub> = 50 pF | 6.4          | 6.9          | ns   |
|                |                              | Slew control = 0 | C <sub>L</sub> = 75 pF | 9.4          | 10.2         |      |
|                |                              | Siew Control – 0 | C <sub>L</sub> = 20 pF | 2.8          | 2.8          |      |
| t <sub>f</sub> | Max fall time                |                  | C <sub>L</sub> = 50 pF | 6.4          | 6.6          | ns   |
|                |                              |                  | C <sub>L</sub> = 75 pF | 9.4          | 9.8          |      |
|                |                              |                  | C <sub>L</sub> = 20 pF | 3.3          | 3.3          |      |
| t <sub>r</sub> | Max rise time                |                  | C <sub>L</sub> = 50 pF | 6.7          | 7.2          | ns   |
|                |                              | Slew control = 1 | C <sub>L</sub> = 75 pF | 9.6          | 10.5         |      |
|                |                              | Siew Control – 1 | C <sub>L</sub> = 20 pF | 3.1          | 3.1          |      |
| t <sub>f</sub> | Max fall time                |                  | C <sub>L</sub> = 50 pF | 6.6          | 6.6          | ns   |
|                |                              |                  | C <sub>L</sub> = 75 pF | 9.6          | 9.6          |      |

(1) Slew control, which is configured by PADxx\_CFG\_REG, changes behavior of the output driver (faster or slower output slew rate).

(2) The rise/fall time is measured as the time taken by the signal to transition from 10% and 90% of VIOIN voltage.

Product Folder Links: AWRL1432

## 7.13.8 Controller Area Network - Flexible Data-rate (CAN-FD)

The CAN-FD module supports both classic CAN and CAN FD (CAN with Flexible Data-Rate) specifications. CAN FD feature allows high throughput and increased payload per data frame. The classic CAN and CAN FD devices can coexist on the same network without any conflict.

### The CAN-FD has the following features:

- Conforms with CAN Protocol 2.0 A, B and ISO 11898-1
- Full CAN FD support (up to 64 data bytes per frame)
- AUTOSAR and SAE J1939 support
- Up to 32 dedicated Transmit Buffers
- Configurable Transmit FIFO, up to 32 elements
- Configurable Transmit Queue, up to 32 elements
- · Configurable Transmit Event FIFO, up to 32 elements
- · Up to 64 dedicated Receive Buffers
- Two configurable Receive FIFOs, up to 64 elements each
- Up to 128 11-bit filter elements
- Internal Loopback mode for self-test
- · Mask-able interrupts, two interrupt lines
- Two clock domains (CAN clock / Host clock)
- Parity / ECC support Message RAM single error correction and double error detection (SECDED)
  mechanism
- Full Message Memory capacity (4352 words).

#### 7.13.8.1 Dynamic Characteristics for the CANx TX and RX Pins

| PARAMETER                 |   | MIN | TYP | MAX | UNIT |
|---------------------------|---|-----|-----|-----|------|
| t <sub>d(CAN_FD_tx)</sub> | Delay time, transmit shift register to CAN_FD_tx pin <sup>(1)</sup> |     |     | 15  | ns   |
| t <sub>d(CAN_FD_rx)</sub> | Delay time, CAN_FD_rx pin to receive shift register <sup>(1)</sup>  |     |     | 15  | ns   |

<sup>(1)</sup> These values do not include rise/fall times of the output buffer.

#### 7.13.9 Serial Communication Interface (SCI)

The SCI has the following features:

- · Standard universal asynchronous receiver-transmitter (UART) communication
- Supports full- or half-duplex operation
- Standard non-return to zero (NRZ) format
- Double-buffered receive and transmit functions in compatibility mode
- Supports two individually enabled interrupt lines: level 0 and level 1
- Configurable frame format of 3 to 13 bits per character based on the following:
  - Data word length programmable from one to eight bits
  - Additional address bit in address-bit mode
  - Parity programmable for zero or one parity bit, odd or even parity
  - Stop programmable for one or two stop bits
- Asynchronous or iso-synchronous communication modes with no CLK pin
- Two multiprocessor communication formats allow communication between more than two devices
- Sleep mode is available to free CPU resources during multiprocessor communication and then wake up to receive an incoming message
- Capability to use Direct Memory Access (DMA) for transmit and receive data
- · Five error flags and Seven status flags provide detailed information regarding SCI events
- Two external pins: RS232\_RX and RS232\_TX
- Multi-buffered receive and transmit units

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#### 7.13.9.1 SCI Timing Requirements

|         |                              | MIN | TYP                  | MAX                 | UNIT  |
|---------|------------------------------|-----|----------------------|---------------------|-------|
| f(baud) | Supported baud rate at 20 pF |     | 115.2 <sup>(1)</sup> | 1250 <sup>(2)</sup> | kBaud |

- Maximum supported standard baud rate.
- Maximum supported custom baud rate.

### 7.13.10 Inter-Integrated Circuit Interface (I2C)

The inter-integrated circuit (I2C) module is a multi-controller communication module providing an interface between devices compliant with Philips Semiconductor I2C-bus specification version 2.1 and connected by an I<sup>2</sup>C-bus<sup>™</sup>. This module will support any target or controller I2C compatible device.

The I2C has the following features:

- Compliance to the Philips I2C bus specification, v2.1 (The I2C Specification, Philips document number 9398 393 40011)
  - Bit/Byte format transfer
  - 7-bit and 10-bit device addressing modes
  - START byte
  - Multi-controller transmitter/ target receiver mode
  - Multi-controller receiver/ target transmitter mode
  - Combined controller transmit/receive and receive/transmit mode
  - Transfer rates of 100 kbps up to 400 kbps (Phillips fast-mode rate)
- Free data format
- Two DMA events (transmit and receive)
- DMA event enable/disable capability
- Module enable/disable capability
- The SDA and SCL are optionally configurable as general purpose I/O
- Slew rate control of the outputs
- Open drain control of the outputs
- Programmable pullup/pulldown capability on the inputs
- Supports Ignore NACK mode

### Note

This I2C module does not support:

- High-speed (HS) mode
- C-bus compatibility mode
- The combined format in 10-bit address mode (the I2C sends the target address second byte every time it sends the target address first byte)

Product Folder Links: AWRL1432

#### 7.13.10.1 I2C Timing Requirements

|                            |   | STANDARD | MODE <sup>(1)</sup> | FAST MO | DE  | UNIT |
|----------------------------|---|----------|---------------------|---------|-----|------|
|                            |   | MIN      | MAX                 | MIN     | MAX | UNII |
| t <sub>c(SCL)</sub>        | Cycle time, SCL   | 10       |                     | 2.5     |     | μs   |
| t <sub>su(SCLH-SDAL)</sub> | Setup time, SCL high before SDA low (for a repeated START condition)          | 4.7      |                     | 0.6     |     | μs   |
| t <sub>h(SCLL-SDAL)</sub>  | Hold time, SCL low after SDA low (for a START and a repeated START condition) | 4        |                     | 0.6     |     | μs   |
| t <sub>w(SCLL)</sub>       | Pulse duration, SCL low   | 4.7      |                     | 1.3     |     | μs   |
| t <sub>w(SCLH)</sub>       | Pulse duration, SCL high  | 4        |                     | 0.6     |     | μs   |
| t <sub>su(SDA-SCLH)</sub>  | Setup time, SDA valid before SCL high   | 250      |                     | 100     |     | μs   |
| t <sub>h(SCLL-SDA)</sub>   | Hold time, SDA valid after SCL low  | 0        | 3.45 <sup>(1)</sup> | 0       | 0.9 | μs   |
| t <sub>w(SDAH)</sub>       | Pulse duration, SDA high between STOP and START conditions                    | 4.7      |                     | 1.3     |     | μs   |
| t <sub>su(SCLH-SDAH)</sub> | Setup time, SCL high before SDA high (for STOP condition)                     | 4        |                     | 0.6     |     | μs   |
| t <sub>w(SP)</sub>         | Pulse duration, spike (must be suppressed)                                    |          |                     | 0       | 50  | ns   |
| C <sub>b</sub> (2) (3)     | Capacitive load for each bus line   |          | 400                 |         | 400 | pF   |

- (1) The I2C pins SDA and SCL do not feature fail-safe I/O buffers. These pins could potentially draw current when the device is powered down.
- (2) The maximum t<sub>h(SDA-SCLL)</sub> for I2C bus devices has only to be met if the device does not stretch the low period (t<sub>w(SCLL)</sub>) of the SCL signal.
- (3) C<sub>b</sub> = total capacitance of one bus line in pF. If mixed with fast-mode devices, faster fall-times are allowed.

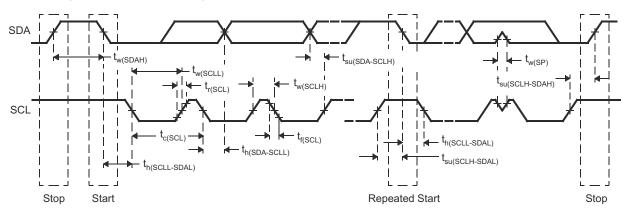


Figure 7-17. I2C Timing Diagram

## Note

- A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the VIHmin of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- The maximum  $t_{h(SDA-SCLL)}$  has only to be met if the device does not stretch the LOW period  $(t_{w(SCLL)})$  of the SCL signal. E.A Fast-mode I2C-bus device can be used in a Standard-mode I2C-bus system, but the requirement  $t_{su(SDA-SCLH)} \ge 250$  ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line tr max +  $t_{su(SDA-SCLH)}$ .

## 7.13.11 Quad Serial Peripheral Interface (QSPI)

The quad serial peripheral interface (QSPI) module is a kind of SPI module that allows single, dual, or quad read access to external SPI devices. This module has a memory mapped register interface, which provides a direct interface for accessing data from external SPI devices and thus simplifying software requirements. The QSPI works as a controller only. The QSPI in the device is primarily intended for fast booting from quad-SPI flash memories.

The QSPI supports the following features:

- · Programmable clock divider
- Six-pin interface
- Programmable length (from 1 to 128 bits) of the words transferred
- Programmable number (from 1 to 4096) of the words transferred
- Optional interrupt generation on word or frame (number of words) completion
- Programmable delay between chip select activation and output data from 0 to 3 QSPI clock cycles

Section 7.13.11.2 and Section 7.13.11.3 assume the operating conditions stated in Section 7.13.11.1.

### 7.13.11.1 QSPI Timing Conditions

|                   |                         | MIN | TYP MAX | UNIT |
|-------------------|-------------------------|-----|---------|------|
| Input Condit      | ions                    |     |         |      |
| t <sub>R</sub>    | Input rise time         | 1   | 3       | ns   |
| t <sub>F</sub>    | Input fall time         | 1   | 3       | ns   |
| Output Cond       | litions                 |     |         |      |
| C <sub>LOAD</sub> | Output load capacitance | 2   | 15      | pF   |

### 7.13.11.2 Timing Requirements for QSPI Input (Read) Timings

|                         |   | MIN <sup>(1)</sup> (2) | TYP | MAX | UNIT |
|-------------------------|---|------------------------|-----|-----|------|
| t <sub>su(D-SCLK)</sub> | Setup time, d[3:0] valid before falling sclk edge                 | 5                      |     |     | ns   |
| t <sub>h(SCLK-D)</sub>  | Hold time, d[3:0] valid after falling sclk edge                   | 1                      |     |     | ns   |
| t <sub>su(D-SCLK)</sub> | Setup time, final d[3:0] bit valid before final falling sclk edge | 5 – P <sup>(3)</sup>   |     |     | ns   |
| t <sub>h(SCLK-D)</sub>  | Hold time, final d[3:0] bit valid after final falling sclk edge   | 1 + P <sup>(3)</sup>   |     |     | ns   |

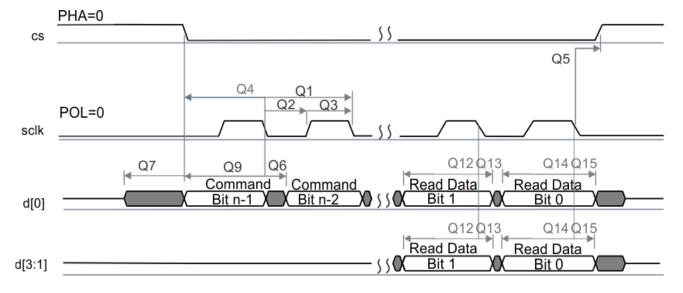
- (1) Clock Mode 0 (clk polarity = 0; clk phase = 0) is the mode of operation.
- (2) The Device captures data on the falling clock edge in Clock Mode 0, as opposed to the traditional rising clock edge. Although non-standard, the falling-edge-based setup and hold time timings have been designed to be compatible with standard SPI devices that launch data on the falling edge in Clock Mode 0.
- (3) P = SCLK period in ns.

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### 7.13.11.3 QSPI Switching Characteristics

| NO. |                           | PARAMETER   | MIN                         | TYP MAX                   | UNIT |
|-----|---------------------------|---|-----------------------------|---------------------------|------|
| Q1  | t <sub>c(SCLK)</sub>      | Cycle time, sclk  | 12.5                        |                           | ns   |
| Q2  | t <sub>w(SCLKL)</sub>     | Pulse duration, sclk low  | Y*P - 3 <sup>(1)</sup> (2)  |                           | ns   |
| Q3  | t <sub>w(SCLKH)</sub>     | Pulse duration, sclk high   | Y*P - 3 <sup>(1)</sup> (2)  |                           | ns   |
| Q4  | t <sub>d(CS-SCLK)</sub>   | Delay time, sclk falling edge to cs active edge                                 | -M*P - 1 <sup>(2) (3)</sup> | -M*P + 2.5 <sup>(2)</sup> | ns   |
| Q5  | t <sub>d(SCLK-CS)</sub>   | Delay time, sclk falling edge to cs inactive edge                               | N*P – 1 <sup>(2) (3)</sup>  | N*P + 2.5 <sup>(2)</sup>  | ns   |
| Q6  | t <sub>d(SCLK-D1)</sub>   | Delay time, sclk falling edge to d[1] transition                                | -2                          | 4                         | ns   |
| Q7  | t <sub>ena(CS-D1LZ)</sub> | Enable time, cs active edge to d[1] driven (lo-z)                               | –P − 4 <sup>(2)</sup>       | -P +1 <sup>(2)</sup>      | ns   |
| Q8  | t <sub>dis(CS-D1Z)</sub>  | Disable time, cs active edge to d[1] tri-stated (hi-z)                          | −P − 4 <sup>(2)</sup>       | -P +1 <sup>(2)</sup>      | ns   |
| Q9  | t <sub>d(SCLK-D1)</sub>   | Delay time, sclk first falling edge to first d[1] transition (for PHA = 0 only) | -2 - P <sup>(2)</sup>       | 4- P <sup>(2)</sup>       | ns   |
| Q12 | t <sub>su(D-SCLK)</sub>   | Setup time, d[3:0] valid before falling sclk edge                               | 5                           |                           | ns   |
| Q13 | t <sub>h(SCLK-D)</sub>    | Hold time, d[3:0] valid after falling sclk edge                                 | 1                           |                           | ns   |
| Q14 | t <sub>su(D-SCLK)</sub>   | Setup time, final d[3:0] bit valid before final falling sclk edge               | 5 — P <sup>(2)</sup>        |                           | ns   |
| Q15 | t <sub>h(SCLK-D)</sub>    | Hold time, final d[3:0] bit valid after final falling sclk edge                 | 1 + P <sup>(2)</sup>        |                           | ns   |

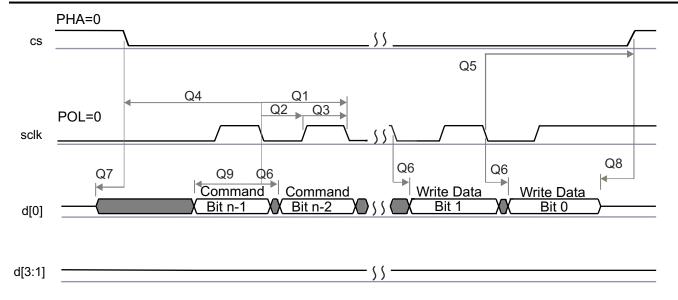
- (1) The Y parameter is defined as follows: If DCLK\_DIV is 0 or ODD then, Y equals 0.5. If DCLK\_DIV is EVEN then, Y equals (DCLK\_DIV/2) / (DCLK\_DIV+1). For best performance, it is recommended to use a DCLK\_DIV of 0 or ODD to minimize the duty cycle distortion. All required details about clock division factor DCLK\_DIV can be found in the device-specific Technical Reference Manual.
- (2) P = SCLK period in ns.
- (3)  $M = QSPI\_SPI\_DC\_REG.DDx + 1, N = 2$



SPRS85v TIMING OSPI1 02

Figure 7-18. QSPI Read (Clock Mode 0)





SPRS85v\_TIMING\_OSPI1\_04

Figure 7-19. QSPI Write (Clock Mode 0)

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## 7.13.12 JTAG Interface

Section 7.13.12.2 and Section 7.13.12.3 assume the operating conditions stated in Section 7.13.12.1.

## 7.13.12.1 JTAG Timing Conditions

|                   |                         | MIN | TYP MAX | UNIT |
|-------------------|-------------------------|-----|---------|------|
| Input Condi       | tions                   |     |         |      |
| t <sub>R</sub>    | Input rise time         | 1   | 3       | ns   |
| t <sub>F</sub>    | Input fall time         | 1   | 3       | ns   |
| Output Con        | Dutput Conditions       |     |         |      |
| C <sub>LOAD</sub> | Output load capacitance | 2   | 15      | pF   |

## 7.13.12.2 Timing Requirements for IEEE 1149.1 JTAG

| NO. |                          |   | MIN   | TYP | MAX | UNIT |
|-----|--------------------------|---|-------|-----|-----|------|
| 1   | t <sub>c(TCK)</sub>      | Cycle time TCK                          | 66.66 |     |     | ns   |
| 1a  | t <sub>w(TCKH)</sub>     | Pulse duration TCK high (40% of tc)     | 20    |     |     | ns   |
| 1b  | t <sub>w(TCKL)</sub>     | Pulse duration TCK low(40% of tc)       | 20    |     |     | ns   |
| 2   | t <sub>su(TDI-TCK)</sub> | Input setup time TDI valid to TCK high  | 2.5   |     |     | ns   |
| 3   | t <sub>su(TMS-TCK)</sub> | Input setup time TMS valid to TCK high  | 2.5   |     |     | ns   |
| 4   | t <sub>h(TCK-TDI)</sub>  | Input hold time TDI valid from TCK high | 18    |     |     | ns   |
| 4   | t <sub>h(TCK-TMS)</sub>  | Input hold time TMS valid from TCK high | 18    |     |     | ns   |

## 7.13.12.3 Switching Characteristics Over Recommended Operating Conditions for IEEE 1149.1 JTAG

| NO. |                           | PARAMETER                        |   |  | MAX | UNIT |
|-----|---------------------------|----------------------------------|---|--|-----|------|
| 2   | t <sub>d(TCKL-TDOV)</sub> | Delay time, TCK low to TDO valid | 0 |  | 15  | ns   |

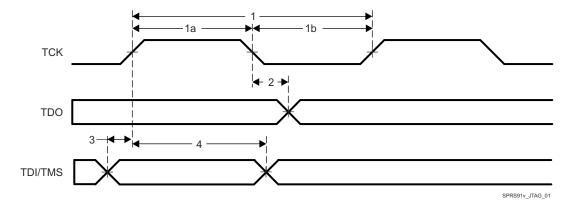


Figure 7-20. JTAG Timing

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# **8 Detailed Description**

### 8.1 Overview

The AWRL1432 device is a complete SOC which include mmWave front end, customer programmable MCU and analog baseband signal chain for two transmitters and three receivers. This device is applicable as a radar-on-a-chip in use-cases with quality provision for memory, processing capacity, and application code size. These could be cost-effective automotive applications that are evolving from 24-GHz narrowband implementation and some emerging radar applications. Typical application examples for this device include gesture detection and kick sensor. In terms of scalability, the AWRL1432 device could be paired with a low-end external MCU, to address more complex applications that might require additional memory for larger application software footprint and faster interfaces. The AWRL1432 device also provides high speed data interfaces like RDIF and is suitable for ADC capture.

Product Folder Links: AWRL1432



## 8.2 Functional Block Diagram

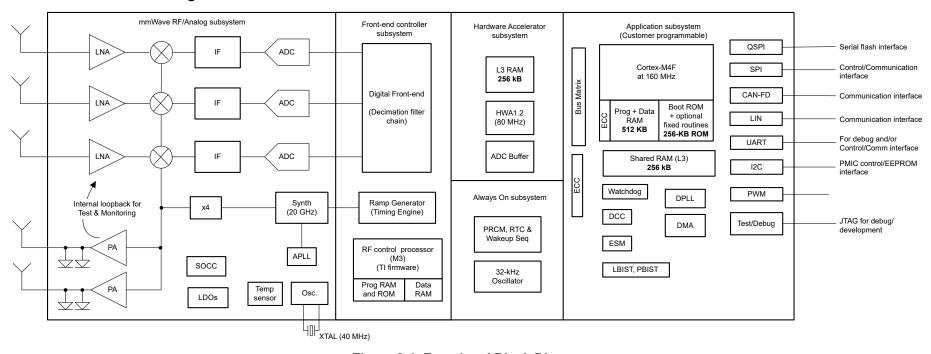


Figure 8-1. Functional Block Diagram

### 8.3 Subsystems

### 8.3.1 RF and Analog Subsystem

The RF and analog subsystem includes the RF and analog circuitry – namely, the synthesizer, PA, LNA, mixer, IF, and ADC. This subsystem also includes the crystal oscillator and temperature sensors. The two TX can be operated simultaneously for beam forming in BPM mode or individually in TDM mode. Similarly, the device allows configuring the number of receive channels based on application and power requirements. For system power saving, RF and analog subsystems can be put into low power mode configuration.

### 8.3.2 Clock Subsystem

The AWRL1432 clock subsystem generates 76 to 81 GHz from an input reference from a crystal. It has a built-in oscillator circuit followed by a clean-up PLL and a RF synthesizer circuit. The output of the RF synthesizer is then processed by an X4 multiplier to create the required frequency in the 76 to 81 GHz spectrum. The RF synthesizer output is modulated by the timing engine block to create the required waveforms for effective sensor operation.

The clean-up PLL also provides a reference clock for the host processor after system wakeup.

The clock subsystem also has built-in mechanisms for detecting the presence of a crystal and monitoring the quality of the generated clock.

Figure 8-2 describes the clock subsystem.

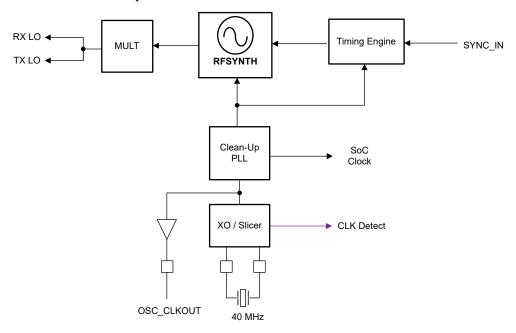


Figure 8-2. Clock Subsystem

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## 8.3.3 Transmit Subsystem

The AWRL1432 transmit subsystem consists of two parallel transmit chains, each with independent phase and amplitude control. The device supports binary phase modulation for MIMO radar.

The transmit chains also support programmable backoff for system optimization.

Figure 8-3 describes the transmit subsystem.

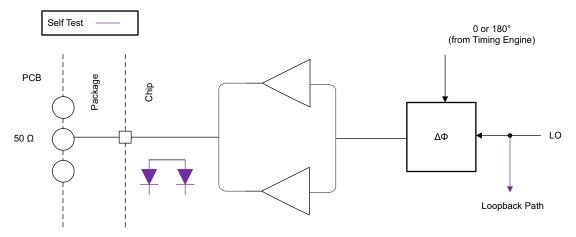


Figure 8-3. Transmit Subsystem (Per Channel)

#### 8.3.4 Receive Subsystem

The AWRL1432 receive subsystem consists of three parallel channels. A single receive channel consists of an LNA, mixer, IF filtering, ADC conversion, and decimation. All three receive channels can either operate simultaneously OR can be powered down individually based on system power needs and application design.

The AWRL1432 device supports a real baseband architecture, which uses real mixer, single IF and ADC chains to provide output for each receiver channel. The device is targeted for fast chirp systems. The band-pass IF chain has configurable lower cutoff frequencies above 175 kHz and can support bandwidths up to 5 MHz.

Figure 8-4 describes the receive subsystem.

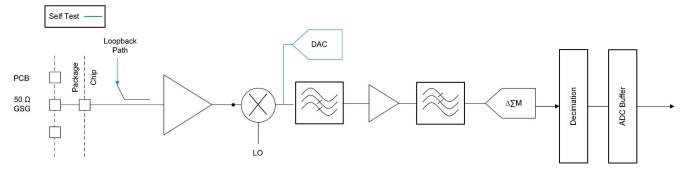


Figure 8-4. Receive Subsystem (Per Channel)

### 8.3.5 Processor Subsystem

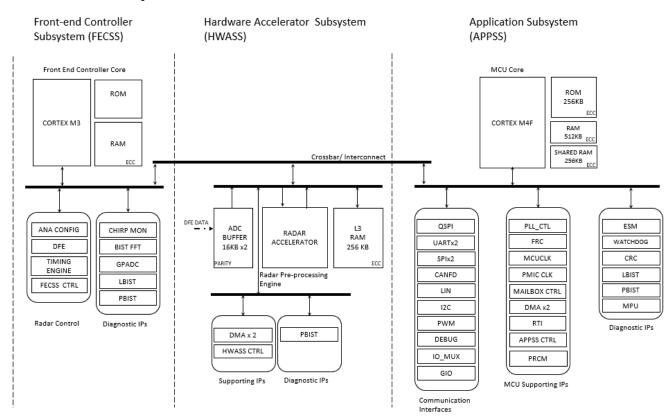


Figure 8-5. Processor Subsystem

Figure 8-5 shows the block diagram for customer programmable processor subsystems in the AWRL1432 device. At a high level there are two customer programmable subsystems, as shown separated by a dotted line in the diagram. The left hand side shows the HWA, a high-bandwidth interconnect for high performance (64-bit, 80MHz), and associated peripherals data transfer. RDIF interface for Measurement data output, L3 Radar data cube memory, the ADC buffers, the CRC engine, and data handshake memory (additional memory provided on interconnect).

The right side of the diagram shows the Main Subsystem. The Main Subsystem is the brain of the device and controls all the device peripherals and house-keeping activities of the device. The Main Subsystem contains Cortex-M4F processor and associated peripherals and house-keeping components such as DMAs, CRC and Peripherals (I<sup>2</sup>C, UART, SPIs, CAN, PMIC clocking module, PWM, LIN,and others) connected to Main Interconnect through Peripheral Central Resource (PCR interconnect).

#### 8.3.6 Automotive Interface

The AWRL1432 communicates with the automotive network over the following main interfaces:

- CAN-FD
- LIN



#### 8.3.7 Host Interface

The host interface can be provided through a SPI, LIN, UART, or CAN-FD interface.

The AWRL1432 device communicates with the host radar processor over the following main interfaces:

- Reference Clock Reference clock available for host processor after device wakeup
- Control 4-port standard SPI (peripheral) for host control. All radio control commands (and response) flow through this interface.
- Reset Active-low reset for device wakeup from host.
- · Host Interrupt an indication that the mmWave sensor needs host interface
- Error Used for notifying the host in case the radio controller detects a fault

## 8.3.8 Application Subsystem

The Application system includes an ARM Cortex M4F processor clocked with a maximum operating frequency of 160 MHz. User applications executing on this processor control the overall operation of the device, including radar control through well-defined API messages, radar signal processing (assisted by the radar hardware accelerator), and peripherals for external interfaces.

See the Technical Reference Manual for a complete description and memory map.

### 8.3.9 Hardware Accelerator (HWA1.2) Features

- Fast FFT computation, with programmable 2<sup>N</sup> sizes, up to 1024-point complex FFT
- Internal FFT bit-width of 24 bits for good Signal-to-Quantization-Noise Ratio (SQNR) performance
- Fully programmable butterfly scaling at every radix-2 stage for user flexibility
- Built-in capabilities for pre-FFT processing Ex: DC estimation and subtraction
- DC estimation & subtraction, Interference estimation & zero-out, Real window, Complex pre-multiplication
- Magnitude (absolute value) and Log-magnitude computation
- Flexible data flow and data sample arrangement to support efficient multi-dimensional FFT operations and transpose accesses
- Chaining and looping mechanism to sequence a set of operations one after another with minimal intervention from the main processor
- Peak detection CFAR (CFAR-CA, CFAR-OS) detector
- Basic statistics, including Sum and 1D Max
- Compression engine for radar cube memory optimization



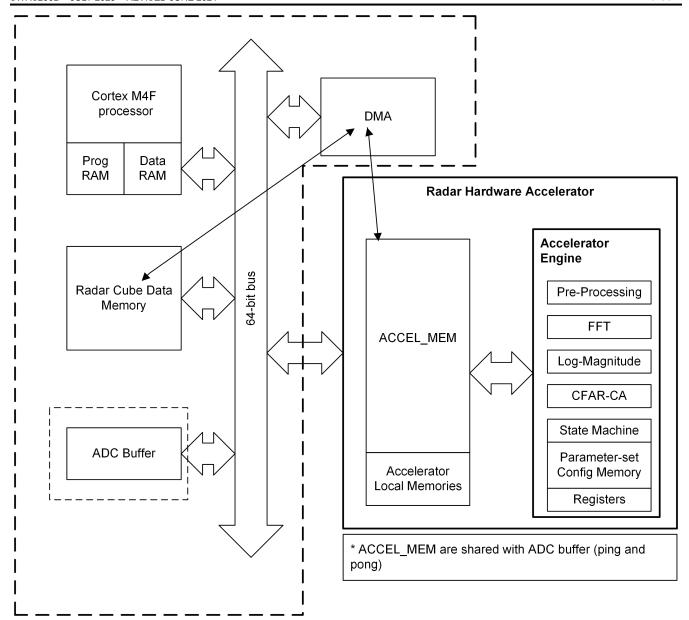


Figure 8-6. HWA 1.2 Functional Block Diagram

# 8.3.9.1 Hardware Accelerator Feature Differences Between HWA1.1 and HWA1.2

| Feature                                |                    | HWA1.0, HWA1.1<br>(xWR1843, xWR6843)         | HWA1.2<br>(xWRL6432, xWRL1432)               |
|--|--------------------|--|--|
|  | FFT sizes          | 1024, 512, 256,                              | 1024, 512, 256,                              |
|  | Internal bit-width | 24-bit I, 24-bit Q                           | 24-bit I, 24-bit Q                           |
| FFT features                           |                    | Configurable butterfly scaling at each stage | Configurable butterfly scaling at each stage |
|  | FFT stitching      | up to 4096 point                             | up to 4096 point                             |
| FFT benchmark for <u>four</u> 256-pt F | FTs                | 1312 clock cycles<br>(6.56 µs at 200 MHz)    | 1320 clock cycles<br>(16.5 µs at 80 MHz)     |
|  |                    | 16   | 32   |
|  |                    | 64KB   | 64KB   |

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HWA1.0, HWA1.1 **HWA1.2 Feature** (xWR1843, xWR6843) (xWRL6432, xWRL1432) A and B-dim addressing of A and B-dim addressing of Input and Output formatter local memory local memory Programmable scaling Programmable scaling DC estimation and subtraction Interference zero out with Interference zero out with fixed threshold, based on adaptive statistics, based on magnitude mag, mag-diff. Interference Pre-FFT processing Complex multiplication (7 count indication. modes) Complex multiplication (7 Real window coefficients modes) Real window coefficients Log-magnitude (0.06 dB Post-FFT processing Log-magnitude (0.3 dB accuracy) accuracy) Not available in HWA1.0 Compression and De-compression support (xWR1843), Available in HWA1.1 Available (xWR6843) CFAR-CA (linear and log Detection CFAR-CA (linear and log modes) CFAR-OS (window size up to 32 on each side) Statistics 1D Sum, 1D Max 1D Sum, 1D Max

## 8.4 Other Subsystems

## 8.4.1 GPADC Channels (Service) for User Application

The AWRL1432 device includes provision for an ADC service for user application, where the GPADC engine present inside the device can be used to measure up to two external voltages. The GPADC1, and GPADC2 pins are used for this purpose.

- GPADC itself is controlled by TI firmware running inside the FEC subsystem and access to it for customer's
  external voltage monitoring purpose is via 'APPSS' calls routed to the FEC subsystem. This API could be
  linked with the user application running on APPSS Cortex M4F<sup>®</sup>.
- Device Firmware package (DFP) provides APIs to configure and measure these signals. The API allows
  configuring the settling time (number of ADC samples to skip) and number of consecutive samples to take.
  At the end of a frame, the minimum, maximum and average of the readings will be reported for each of the
  monitored voltages.



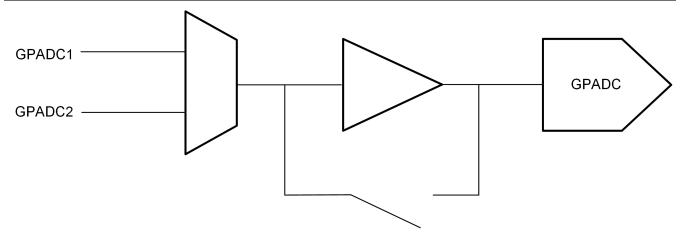


Figure 8-7. GPADC Path

GPADC structures are used for measuring the output of internal temperature sensors. The accuracy of these measurements is  $\pm 7^{\circ}$ C.

## 8.4.2 GPADC Parameters

| PARAMETER                                       | TYP       | UNIT |
|---|-----------|------|
| ADC supply                                      | 1.8       | V    |
| ADC unbuffered input voltage range              | 0 – 1.8   | V    |
| ADC buffered input voltage range <sup>(1)</sup> | 0.4 – 1.3 | V    |
| ADC resolution                                  | 8         | bits |
| ADC offset error                                | ±5        | LSB  |
| ADC gain error                                  | ±5        | LSB  |
| ADC DNL   | -1/+2.5   | LSB  |
| ADC INL   | ±2.5      | LSB  |
| ADC sample rate <sup>(2)</sup>                  | 831       | Ksps |
| ADC sampling time <sup>(2)</sup>                | 300       | ns   |
| ADC internal cap                                | 10        | pF   |
| ADC buffer input capacitance                    | 2         | pF   |
| ADC input leakage current                       | 3         | uA   |

- (1) Outside of given range, the buffer output will become nonlinear.
- (2) GPADC itself is controlled by TI firmware running inside the BIST subsystem. For more details please refer to the API calls.

## 8.5 Memory Partitioning Options

AWRL1432 devices will have a total memory of 1MB. The L3 memory has two memory banks and can be associated with radar cube memory or with the Cortex-M4F RAM.

**Table 8-1. Memory Partition Options** 

|                                     |  | Config 1 | Config 2 | Config 3 |
|-------------------------------------|--|----------|----------|----------|
| Radar data memory* (L3)             | Includes data cube, detection matrix, heatmap          | 256KB    | 384kB    | 512KB    |
| Application<br>(M4F program + data) | Includes drivers,<br>mmWavelink, BIOS (and<br>AUTOSAR) | 768KB    | 640KB    | 512KB    |
| Total memory                        |  | 1024KB   | 1024KB   | 1024KB   |

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The entire RAM is retainable. Additionally, each memory cluster can be independently turned off (if needed). The clusters are defined as below

**Table 8-2. Memory Retention Options** 

|                        | RAM_1      |            | RA         | M_2        | RAM_3 | Shared     | HWA   |
|------------------------|------------|------------|------------|------------|-------|------------|-------|
| 256KB                  |            | 128KB      |            | 128KB      | 256KB | 256KB      |       |
| BANK #1 <sup>(1)</sup> |            | BAN        | K #2       | BANK #3    |       |            |       |
| Cluster #1             | Cluster #3 | Cluster #4 | Cluster #2 | Cluster #5 |       | Cluster #6 |       |
| 64kB                   | 64KB       | 128KB      | 16KB       | 112KB      | 128KB | 256KB      | 256KB |

<sup>(1)</sup> Retention memories have power switches. These Banks represent memory configurations.

#### 8.6 Boot Modes

As soon as device reset is de-asserted, the processor of the APPSS starts executing its bootloader from an on-chip ROM memory.

The bootloader operates in three basic modes and these are specified on the user hardware (Printed Circuit Board) by configuring what are termed as "Sense on power" (SOP) pins. These pins on the device boundary are scanned by the bootloader firmware and choice of mode for bootloader operation is made.

Table 8-3 enumerates the relevant SOP combinations and how these map to bootloader operation.

### **Table 8-3. SOP Combinations**

| SOP1 | SOP0 | BOOTLOADER MODE AND OPERATION   |
|------|------|---|
| 0    | 0    | Flashing Mode  Device Bootloader spins in loop to allow flashing of user application (or device firmware patch - Supplied by TI) to the serial flash. |
| 0    | 1    | Functional Mode  Device Bootloader loads user application from QSPI Serial Flash to internal RAM and switches the control to it.                      |
| 1    | 1    | Debug Mode  Bootloader is bypassed and M4F processor is halted. This allows user to connect emulator at a known point.                                |



# 9 Monitoring and Diagnostics

For details on monitioring and functional safety implementation, refer to the Technical Reference Manual.

Monitoring DFP API usage is shown in mmWave demos of the low power mmWave SDK, MMWAVE-L-SDK. Please refer to documentation in *ICD* (*Interface control Document*), for more details.

Refer to the *Device Safety Manual* or other relevant collaterals for more details on applicability of all diagnostics mechanisms.

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# 10 Applications, Implementation, and Layout

### Note

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## **10.1 Application Information**

Application information can be found on AWR Application web page.

#### 10.2 Reference Schematic

Please check the device product page for latest Hardware design information under Design Kits - typically, at Design and Development

Listed for convenience are: Design Files, Schematics, Layouts, and Stack up for PCB

- Altium AWRL1432 EVM Design Files
- AWRL1432 EVM Schematic Drawing, Assembly Drawing, and Bill of Materials

## 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions follow.

### 11.1 Device Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all microprocessors (MPUs) and support tools. Each device has one of three prefixes: X, P, or null (no prefix) (for example, *AWRL1432*). Texas Instruments recommends two of three possible prefix designators for its support tools: TMDX and TMDS. These prefixes represent evolutionary stages of product development from engineering prototypes (TMDX) through fully qualified production devices and tools (TMDS).

Device development evolutionary flow:

- **X** Experimental device that is not necessarily representative of the final device's electrical specifications and may not use production assembly flow.
- **P** Prototype device that is not necessarily the final silicon die and may not necessarily meet final electrical specifications.

null Production version of the silicon die that is fully qualified.

Support tool development evolutionary flow:

**TMDX** Development-support product that has not yet completed Texas Instruments internal qualification testing. **TMDS** Fully-qualified development-support product.

X and P devices and TMDX development-support tools are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

Production devices and TMDS development-support tools have been characterized fully, and the quality and reliability of the device have been demonstrated fully. Tl's standard warranty applies.

Predictions show that prototype devices (X or P) have a greater failure rate than the standard production devices. Texas Instruments recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the package type (for example, ABL0161), the temperature range (for example, blank is the default commercial temperature range). Figure 11-1 provides a legend for reading the complete device name for any *AWRL1432*device.

For orderable part numbers of *AWRL1432* devices in the ABL0161 package types, see the Package Option Addendum of this document (when available), the TI website (www.ti.com), or contact your TI sales representative.

For additional description of the device nomenclature markings on the die, see the AWRL1432 Device Errata ..

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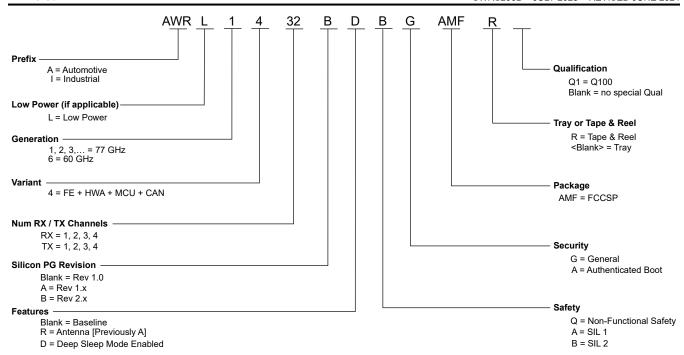


Figure 11-1. Device Nomenclature

#### 11.2 Tools and Software

#### Models

AWRL1432 BSDL model Boundary scan database of testable input and output pins for IEEE 1149.1 of the specific device.

AWRL1432 IBIS model IO buffer information model for the IO buffers of the device. For simulation on a circuit board, see IBIS Open Forum.

### 11.3 Documentation Support

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

The current documentation that describes the peripherals, and other technical collateral follows.

## Errata

AWRL1432 Device Errata . Describes known advisories, limitations, and cautions on silicon and provides workarounds.

### 11.4 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help—straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 11.5 Trademarks

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## 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 11.7 Glossary

| TI Glossary | This glossary lists and explains terms, acronyms, and definitions. |
|-------------|--|

# 12 Revision History

| Changes from July 1, 2023 to February 28, 2024 (from Revision * (July 2023) to Revision A |   |                |  |  |  |
|---|---|----------------|--|--|--|
| (F  | (February 2024)) Pa   |                |  |  |  |
| •   | (Description): Updated the applications   | <mark>2</mark> |  |  |  |
| •   | (Description): Updated the packaging variants information in the table                    | 2              |  |  |  |
| •   | (Power Supply Sequencing): Updated the SOP sequence. 1.2V, 1.8V and VIOIN power up synced | 32             |  |  |  |

Changes from February 28, 2024 to June 12, 2024 (from Revision A (February 2024) to

| R | evision B (June 2024))  | Page            |
|---|---|-----------------|
| • | (Features) : Updated typical Noise figure to 14dB   | 1               |
| • | (Description): Updated the packaging variants information in the table                                | 2               |
| • | (Device Comparison): Added note for "Compliance targeted" devices                                     | 6               |
| • | (Signal Descriptions): Updated the incorrect pin signal name, descriptions and mappings               | 10              |
| • | (Signal Descriptions): Moved the Pin Type column before Description column. Incorrect pin description |                 |
|   | mappings are corrected  | 10              |
| • | (Pin Muxing): Added SOP[0] and SOP[1] pin muxing details in the table                                 | 14              |
| • | (Pin Muxing): Moved PULL UP/DOWN TYPE column to the last column                                       | 14              |
| • | (VPP Specification): Added new section with VPP specifications  | 19              |
| • | (BOM Optimized 3.3V I/O Topology) : Added VNWA  | 21              |
| • | (BOM Optimized 1.8V I/O Topology): VNWA added   |                 |
| • | (System Topologies): Added description for each of the two system topologies                          | <mark>22</mark> |
| • | (Power Topologies): Updated introduction with more information regarding the two power topologies     | <mark>22</mark> |
| • | (Internal LDO output De-cap and layout conditions for BOM optimized topology): Added new section      |                 |
|   | addressing range for de-coupling capacitor values and output path parasitic values                    |                 |
| • | (Noise and ripple specification): Added 1.8V noise and ripple specification note                      | 26              |
| • | (Typical Power Consumption Numbers): Updated description with device condition and ambient            |                 |
|   | temperature   | <mark>27</mark> |
| • | (Typical Power Consumption Numbers): Updated Estimated Power Consumed in 3.3V IO Mode table           |                 |
|   | Conditions and Power consumption for power optimized and BOM optimized modes                          |                 |
| • | (Typical Power Consumption Numbers): Updated Estimated Power Consumed in 1.8V IO Mode table           |                 |
|   | Conditions and Power consumption for power optimized and BOM optimized modes                          |                 |
| • | (Typical Power Consumption Numbers): Updated the Use-Case Power Consumed in 3.3V Power Opti           |                 |
|   | Topology (Level Sensing Application) table - Conditions and Typical Power consumption value           |                 |
| • | (Typical Power Consumption Numbers): Added the Use-Case Power Consumed in 3.3V Power Optim            |                 |
|   | Topology (Kick to Open Application) table   | <mark>27</mark> |

Product Folder Links: AWRL1432



### www.ti.com

| • | (Peak Current Requirement per Voltage Rail) : Updated the Maximum current for each power rail is updated in the table | ted<br>28 |
|---|---|-----------|
|   | (RF Specification) : Added typical Noise Figure, S11 of Tx and Rx   |           |
|   | (RF Specification): Updated the Noise Figure plot and 1-dB compression point (Out Of Band)                            |           |
| • | (Supported Front End features): Updated title to Supported Front End Features from Supported DFE                      |           |
|   | features  | 31        |
| • | (Supported Front End features): Updated supported ADC sampling rates  | 31        |
| • | (Supported Front End features): Updated timing engine paragraph   |           |
| • | (Supported Front End features): Updated chirp profile supported by timing engine figure                               | 31        |
| • | (Supported Front End features) : Added note   | - 4       |
| • | (Power Supply Sequencing): Updated the SOP sequence   | 32        |
| • | (Clock Specifications): Corrected the External Clock Mode Specifications table - units of DC Voltages                 | 34        |
| • | (RDIF Interface Configuration): Removed the 100Mbps from supported data rates   | 42        |
| • | (LIN): Corrected the Baud rate unit and pin names   | 43        |
| • | (SCI Timing Requirements) : Added the supported baud rates  |           |
| • | (Clock Subsystem) : Updated Clock Subsystem diagram   | 54        |
| • | (Application Subsystem): Updated the section name and description from Main Subsystem to Application                  | ì         |
|   | Subsystem   | 57        |
| • | (GPADC channels) : Included the APPSS Cortex M4F®   | 59        |
| • | (Monitoring and Diagnostics) : Added the new section  |           |
| • | (Device Nomenclature): Updated reflecting production part number  |           |
|   |   |           |



# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, see the left-hand navigation.

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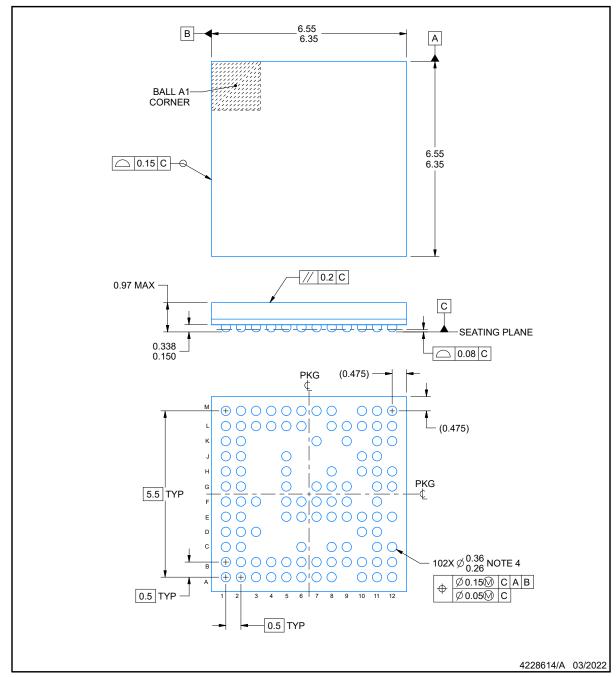
# **AMF0102A**



## PACKAGE OUTLINE

# FCCSP - 0.97 mm max height

FLIP CHIP SCALE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- 2. This drawing is subject to change without notice.
- Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
   Dimension is measured at the maximum solder ball diameter, post reflow, parallel to primary datum C.

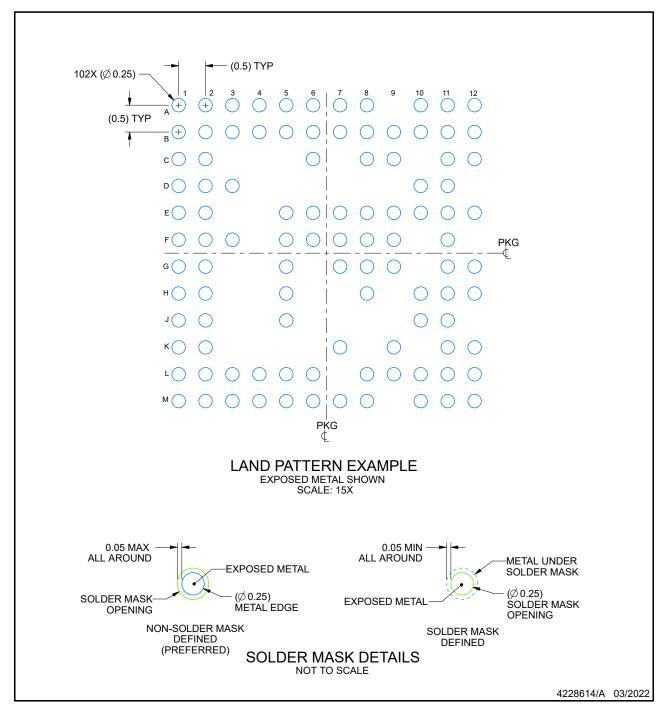


## **EXAMPLE BOARD LAYOUT**

# **AMF0102A**

## FCCSP - 0.97 mm max height

FLIP CHIP SCALE PACKAGE



NOTES: (continued)

5. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

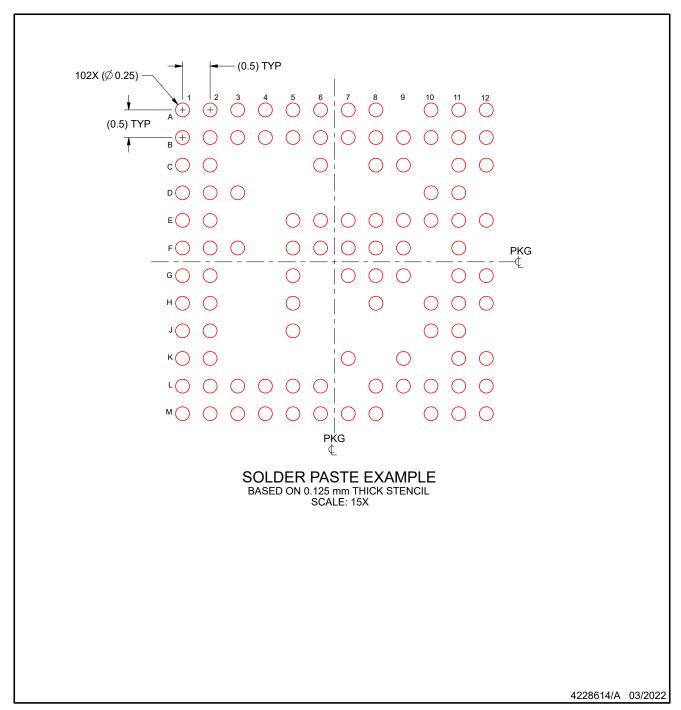


# **EXAMPLE STENCIL DESIGN**

# **AMF0102A**

# FCCSP - 0.97 mm max height

FLIP CHIP SCALE PACKAGE



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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#### PACKAGING INFORMATION

| Orderable Device   | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp       | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|--------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|---------------------|--------------|-------------------------|---------|
| AWRL1432BBAAMFRQ1  | ACTIVE | FCCSP        | AMF                | 102  | 1000           | RoHS & Green | SACQ                          | Level-3-260C-168 HR | -40 to 125   | AWRL1432<br>BB<br>843B  | Samples |
| AWRL1432BDBAAMFRQ1 | ACTIVE | FCCSP        | AMF                | 102  | 1000           | RoHS & Green | SACQ                          | Level-3-260C-168 HR | -40 to 125   | AWRL1432<br>BA<br>843B  | Samples |
| AWRL1432BDBGAMFRQ1 | ACTIVE | FCCSP        | AMF                | 102  | 1000           | RoHS & Green | SACQ                          | Level-3-260C-168 HR | -40 to 125   | AWRL1432<br>BG<br>843B  | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



# PACKAGE OPTION ADDENDUM

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